Introduction

To solve modern issues in materials sciences and nanotechnology, aberration corrected electron microscopy has yielded rich results, which could not be realized without a correction technique. Thus, aberration corrected (AC) electron microscopes is obviously becoming "conventional instruments" in transmission electron microscopy (TEM) [1] and scanning transmission electron microscopy (STEM) [2] for studies of materials and matter. As Feynman [3] and many scientists [4] have dreamed, imaging of individual atom is now reality, but visualizing individual atoms of light elements has yet to be resolved and localization of individual atoms (three dimensional imaging) in matrices has yet to be imaged. New aberration corrected microscope* that achieves a sub-50 pm resolution [5]. The microscope with a cold field emission gun (CFEG) operates at 300 keV and can form a 46 pm electron probe with a 30 mrad semi-angle. This new electron microscope, which is named R005 (Resolution double oh five), has allowed us to detect various atoms; lithium, carbon, nitrogen, oxygen, silicon, arsenic, copper, germanium, silicon, gallium, tungsten, and gold in AC-STEM imaging.

New R005 microscope

Figure 1 shows the view of the new microscope, including the new cold-field emission gun (CFEG) and aberration correctors. A sub-50 pm resolution has been confirmed by imaging '47 pm separated' atomic columns in a germanium crystal [5]. Figure 2 shows the STEM image, where the "dumbbell" image for the atomic columns along [114] are resolved. The observed image accords with the simulation, where the STEM probe has 46 pm FWHM; the coherent probe with the convergent semi-angle of 30 mrad is blurred by the incoherent Gaussian probe of 16 pm diameter. To compare the length scales, Figure 3 displays high angle annular dark field (HAADF)-STEM images of the dumbbell-like structure.

*The project, named "development of a 50 pm resolution aberration-corrected EM for studies of phenomena in materials and matter" was conducted in collaboration with JEOL and Tokyo Tech. with the support of Japan Science and Technology Agency (JST).
Fig. 1 R005 microscope for STEM-TEM imaging at sub-50 pm resolution.

Fig. 2 47 pm spaced dumbbell image of germanium crystal. Each dumbbell are the pair of the [114] atomic columns. (a) HAADF (high angle annular dark field) image, (b) Fourier transform of HAADF image, (c) intensity profile of the boxed area in (a).

Fig. 3 Dumbbell images of [hkl] atomic columns for (a) gallium nitride [211], (b) germanium [112] and (c) silicon [110]. Three panels are displayed with the same length scale; the spacing of the dumbbells are (a) 63 pm, (b) 82 pm, and (c) 136 pm.
bells for the '63 pm' separated [112] Ga columns in a GaN crystal [6], '82 pm' separated [112] germanium columns in a Ge crystal, and '136 pm' separated [110] silicon columns in a Si crystal.

The high performance of the R005 microscope is mainly due to the development of new spherical aberration correctors. The correctors are installed in both probe and image forming systems, namely STEM-Cs and TEM-Cs correctors. Both STEM and TEM Cs correctors have been newly designed to incorporate into the lens system of the microscope, which is dedicated for the present aberration correction system. Each of the aberration correctors is an asymmetrical dodeca-pole system, basically uses a hexapole field to correct spherical aberration as shown in Fig. 4. The asymmetric system allows us to reduce the higher order parasitic aberrations as well as increase of chromatic aberration generated in the transfer lens system resulting in the small increase of chromatic aberration (ΔCc = 0.2 nm) for probe and image forming systems.

A new automatic correction system has been developed to optimize the imaging condition [7]. The system (named Segmental Ronchigram Autocorrelation Matrix (SRAM)) uses Ronchigrams taken from an amorphous area of the specimen to find and correct the aberrations: Auto correlation functions obtained from several segments of the Ronchigram give quadric patterns correlated to the aberrations. The quadric patterns in segments are analyzed to estimate the aberration of the probe as shown in Fig. 5.

Development and design of a new CFEG, a microscope column, stable electronic circuits, and anti-vibration mechanical system have also contributed to the high performance of the R005 microscope. The new CFEG has achieved a constant emission current in excess of eight hours of continuous observations. The long-life and stable emission has enabled quantitative studies in quantitative imaging and in chemical analyses by EELS and EDS to be realized.

The R005 microscope has a new objective lens which has low chromatic aberration coefficients, Cc = 1.65 nm in probe forming system and Cc = 1.54 nm in image forming system, leaving a wide gap space of the objective pole-piece. Moreover, the objective lens is redesigned to observe specimens in aberration corrected STEM and TEM without changing the specimen height. More importantly, the R005 microscope allows any type of side-entry specimen holder that fits conventional JEOL electron microscopes (the models after JEM-2100F). Furthermore, the R005 microscope is capable of in-situ studies.

**Lithium atom detection**

Lithium atoms and ions have increasingly received interest due to their behaviors for applications in rechargeable batteries [8]. Although elaborate studies on TEM imaging of lithium atom columns [9, 10] have been conducted, lithium atoms and ions
have yet to be detected one by one with electron microscopy. Herein we report STEM imaging of individual lithium atoms and detection of a few lithium atoms aligned in a column using the R005 microscope [11].

The R005 microscope with a new CFEG that enables a large convergent angle of the incident probe benefits annular bright field (ABF) STEM imaging, which is analogous, by reciprocity, to the bright field TEM using hollow-cone illumination [12]. Figure 6 shows an ABF image of oxygen columns in MgAl2O4 crystal, where Mg, Al and O columns appear with different darkness after their atomic number difference as recent reports on ABF [13,14].

Figure 7 shows an ABF image of a LiV2O4 [110] crystal with spinel structure (space group, Fd-3m) (cf. Fig. 8(c)). In this view, each dark dot is the image of the [110] atomic column aligned parallel to the incident electron beam direction. Each column contains only vanadium (V), oxygen (O), or lithium (Li) atoms, so that the atomic species of the column can be determined from the darkness of the column image. In Fig. 7 the lithium atomic columns are observable. The image was processed by radial difference filter and low-pass frequency filter on the original raw image to eliminate impeding noises. To demonstrate that the present filtering does not cause artifacts on the raw image, but reduce the speckled noise of the background, Figs. 8(a) and (b) show the raw image and the filtered image, respectively, while Figs. 8(c) and (d) show the structure model and the simulated image at a 3 nm thickness, respectively. The positions of dark dots agree well with the projected structure of LiV2O4 and the simulated image. The simulation reproduces the observed intensity profile as given in Ref [11], although the oxygen columns are not as intense as theoretically predicted.

The ABF and annular dark field (ADF) images, observed simultaneously, were simulated by multi-slice calculations [15,16] to determine specimen thickness in the observation area varying from zero to 3 nm. The ABF images in Figs. 8(a) and (b) are reproduced well by the simulated image for a specimen thickness of 3 nm. Assuming 3 nm thickness, the estimated number of lithium atoms is five, because the lithium atoms are aligned every 0.58 nm after the model structure in Fig. 8(c). Surprisingly, lithium columns in Fig. 7 are visible at thinner area than Fig. 8. At such a thin area below 2 nm thickness, each column can contain only a few lithium atoms. The lithium column and oxygen column are separated by 0.1 nm (c.f., Fig. 8(c)). Thus, the 50 pm resolution is critical for lithium imaging. Therefore, without the present CFEG, which provides a small Gaussian probe of 16 pm diameter, lithium atomic column imaging is not possible. Although aberration correction can improve resolution, a large source size like a Schottky emitter can blur the image and reduce image contrast of the lithium column (see, discussion in ref [5]).

The R005 microscope with a new CFEG has an imaging capability of a few lithium atoms in ABF-STEM, and is promising for lithium microscopy and microanalysis.
Arsenic dopant detection in silicon crystal

The localization and inhomogeneity of atoms and clusters in materials have been the subjects of research for decades [17], because they become more dominant in controlling the materials properties as the length scale decreases. Except for SIMS (secondary ion mass spectroscopy) and ATP (atom probe), few methods are capable of visualizing the three-dimensional distribution of atoms. Here we demonstrate the visualization of individual arsenic dopant atoms in a silicon crystal using AC-STEM. Because high-speed, high-density and economic feasibility are always issues in silicon based transistors, and three-dimensional distribution of arsenic dopants in silicon-based transistors have long been of major interest. Thus, a key to visualizing dopant atoms in silicon devices, which have commercial and research gate lengths of 45 nm and 20 nm, respectively, is to determine how dopants are distributed and how they are clustered to give rise to localization and inhomogeneity. The performance of the R005 microscope should be capable of detecting individual arsenic dopants, although antimony and other heavy dopants have already observed by the STEM [18,19].

Figure 9 schematically depicts how a 50 pm probe receives signals from a dopant atom substituted at the silicon crystal. Additional scattering signals due to the replacement of a silicon atom by a heavy atom is detected in the HAADF images; the scattering signal is intense when the 50 pm probe is focused at (or slightly above) the dopant. Thus, columns with a high intensity, provide a location map of the dopant atoms [20]. Here, CFEG with a small source is critical, because the Gaussian probe size of the source blurs the STEM images [21, 22].

Figure 10 shows a HAADF image [16] of a silicon crystal doped with arsenic atoms at a concentration of 10^20 /cm^3 (6%), viewed from the [100] direction of the silicon crystal. Thus, the bright dots correspond to the atomic columns arranged into a square lattice with ~0.2 nm spacing. The rainbow colors denote the intensities where red (most intense) discriminates columns with a single arsenic atom around the focal point. The red-colored columns indicate that some neighboring pairs have particular arrangements for the dopant clusters illustrated in Fig. 11. For example, the red-pair with the 2nd nearest neighbor distance in Fig. 10 represents the DP2 cluster [23] illustrated in Fig. 11. Figure 10 has a new arrangement, where the pair that looks like the letter 'L', two steps horizontally and one step vertically (or two steps vertically and one step horizontally), represents the FDP cluster [24].

Thus, arsenic dopants in a silicon crystal have been detected. Both CFEG and the high performance of the objective lens of the R005 electron microscope aid in this successful detection which has never been done before.

Single atom detection

Detection of atoms and/or adsorbed atoms on a surface is of interest, particularly in catalysis and crystal growths. The R005 microscope has detected individual atoms of silicon, copper, germanium, silver, tungsten, and gold deposited on an amorphous carbon surface in HAADF-STEM. TEM has also imaged individual atoms, i.e., carbon atoms in a graphene sheet. Here we demonstrate TEM imaging of gold atoms and particles deposited on an amorphous carbon film.

Figure 12 shows a high resolution TEM image of gold deposits observed by the R005 microscope. Isolated atoms, clusters and particles are clearly detected. This image, a shot at the in-focus imaging condition, demonstrates “real” existence of gold atoms. The black dotted images that are dispersed around gold particles are single gold atoms. Their image intensity agrees with the multi-slice simulation. Dynamics of atomic motions are observable by AC-TEM through CCD camera systems. In-situ experiments in AC-TEM give rich information about dynamics of atoms and clusters, aided by the high performance of the R005 microscope.

Concluding Remarks

Aberration corrected electron microscopy with a sub-30 pm resolution has enabled individual atoms, including lithium atoms, to be detected. The advances of the R005 microscope include long-life CFEG, anti-symmetric AC, and an objective pole piece with a very low chromatic aberration. These
advances provide atomic imaging capability in both STEM and TEM modes of operation, which is the first step towards realizing hydrogen imaging.

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References


Fig.11 Structure models of arsenic dopant clusters, (a) DP2, (b) As2V, (c) As4V, and (d) FDP cluster.

Fig.12 TEM image of gold atoms, clusters, and particles deposited on an amorphous carbon surface. Inset shows single gold atoms resolved clearly in the image.
Atomic-Resolution Elemental Mapping by EELS and XEDS in Aberration Corrected STEM

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Introduction

Chemical analysis at atomic-level spatial resolution with single-atom detection sensitivity is one of the ultimate goals in materials characterization. Such atomic-level materials characterization is now possible in the latest aberration-corrected electron microscopes. By aberration correction, image resolution has already reached half-Ångstrom levels by high-angle annular dark-field (HAADF) imaging in scanning transmission electron microscopy (STEM) and phase contrast imaging in transmission electron microscopy (TEM) [1, 2]. In addition, aberration-corrected STEM is also useful for chemical analysis by electron energy-loss spectrometry (EELS) and X-ray energy dispersive spectrometry (XEDS) since more probe current can be added into the aberration-corrected fine probe. Especially for EELS analysis, such higher beam currents may be sufficient to generate core-loss signals for reasonable analysis within a short acquisition time. Atomic-resolution EELS mapping has been already demonstrated in aberration-corrected STEM [3-5]. The aberration-corrected fine probe is also beneficial for XEDS analysis to analyze materials with improved spatial resolution of ~0.4 nm [6].

Elemental mapping in aberration-corrected STEM/TEM is still limited by poor analytical sensitivity due to far much shorter acquisition time per pixel and to extremely small analyzed volumes. By simply increasing acquisition time, atomic-level resolution may be spoiled by spatial drifts of a specimen and/or an incident probe. Increased probe currents to improve analytical sensitivity result in degradation of resolution as the incident probe is enlarged with the current. Therefore, it is essential to optimize probe setting with an appropriate probe currents for atomic resolution analysis. In addition, the poor analytical sensitivity can be offset by applying spectrum imaging (SI) in combination with advanced statistical approaches, such as multivariate statistical analysis (MSA). These methods succeed because the major noise components can be removed efficiently from spectrum acquired for a very short dwell time and then regular spectral processing is potentially applicable. The MSA noise reduction is also applicable to atomic resolution images as well.

In this paper, the optimum probe-formation is discussed first to perform atomic-resolution chemical analysis by EELS and XEDS in aberration-corrected instruments. Then, advantages to employ advanced SI and MSA approaches are demonstrated to extract unexpected information from datasets. Finally, several applications of atomic-resolution chemical images obtained by the recently developed JEM-ARM200F are shown to address future trends in chemical analysis of materials.

Optimum instrument settings for atomic resolution analysis

Spatial resolution in STEM imaging and analysis is directly related to an incident probe dimension; i.e., the shape and diameter in a certain fraction Hence, the incident probe dimension is one of the most important factors in STEM. Most of the probe formation discussed in previous studies are focused on the geometric- and chromatic-aberration limited probe (dealt with a point source) and/or chromatic-aberration limited probe (which represent blurring of a point source). Note that the details about the geometric- and chromatic-aberration limited probe dimension contains any contribution of the finite source size (which is expressed through the source brightness and probe current). Therefore, the geometric- or chromatic-aberration limited probe sizes are useful only for operating conditions with a significantly limited probe current [10], such as high resolution HAADF-STEM imaging. However, for any analytical application by EELS and XEDS, the contribution of the finite source must be taken into account to probe formation since more currents are required to generate sufficient enough signals for appropriate EELS or XEDS analysis [6, 11]. In fact, the probe dimensions are enlarged as a function of the probe current.

Recent improvements in aberration correction have brought tremendous advantages not only in high resolution imaging but also in high resolution analysis by electron energy-loss spectrometry (EELS) and X-ray energy-dispersive spectrometry (XEDS) in scanning transmission electron microscopy (STEM). Once the incident probe formation is optimized, atomic-resolution analysis can be performed by acquiring sufficient enough signals for appropriate chemical analysis while maintaining fine probe sizes. In addition, more sophisticated approaches of data acquisition and analysis, such as spectrum imaging (SI) and multivariate statistical analysis (MSA), are essential for atomic-resolution chemical analyses. In fact, it is possible to obtain atomic-resolution chemical images of materials since both the spatial resolution and analytical sensitivity are improved tremendously in combination of the aberration correction instrument with the advanced acquisition and analysis techniques. In this manuscript, the incident probe formation, data acquisition and data analysis are reviewed for atomic-resolution chemical analysis by EELS and XEDS in aberration-corrected instruments. Then, several applications of atomic-resolution chemical images obtained by the recently developed JEM-ARM200F aberration-corrected microscope are shown to address future trends in chemical analysis of materials.

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residual aberrations can be the 5th-order spherically symmetric with a defocus of –28 nm. In contrast, the 5th-order spherical aberration coefficient ($c_5$) and six-fold astigmatism (A5) are 0.5 mm and 1.2 mm, respectively. With the best aberration coefficients ($c_5 = 0.5$ mm and $A_5 = 0.5$ mm), the geometric-aberration limited probe diameter can reach to 40 pm at ~40 mrad as shown in Fig. 1 (open triangle). In the aberration-corrected condition, the probe size is increased due to the addition of aberration corrector.

As shown in Fig. 1, the optimum probe sizes are 160 pm at 11 mrad and 85 pm at 23 mrad in the conventional and aberration-corrected conditions, respectively. Again, these probe sizes are based on the chromatic-aberration limited intensity distribution and any contribution of the finite source size is not included. For analytical applications, the probe optimization should be performed with the probe current. The overall probe diameters at 11 and 23 mrad in both conventional and aberration-corrected conditions are also plotted.

In this case, the probe diameter was determined with $\Delta E = 1.0$ eV and $C_5^* = 1.4$ mm (slightly increased due to the addition of aberration corrector).

Hence, probe setting should be optimized carefully to maintain the high spatial resolution in atomic level with sufficient probe currents for better analytical sensitivity. Here, the optimum probe setting for atomic resolution analysis is discussed first [12].

**Figure 1** shows the diameter containing 59% of total intensity (d(59%)), determined from the simulated intensity distribution of chromatic-aberration limited probe in conventional and aberration-corrected conditions for a 200 kV JEOL instrument equipped with a Schottky field-emission gun (FEG) source, which are plotted as a function of the probe-forming semi-angle, $\alpha$. In both conditions, the electron energy-spread ($\Delta E$) of 1.0 eV that is a common value for the Schottky FEG was used. Note that the definition of d(59%) is originally derived from the Rayleigh criterion of intensity distribution in the aperture-diffraction limited probe, by which the image resolution can be defined as the minimum distance to distinguish the two point objects [9, 13, 14]. In the conventional condition, the simulation was performed for a 200 kV JEOL instrument with a ultra-high resolution pole-piece (the 3rd-order spherical aberration coefficient $C_3$ of 0.5 mm and the chromatic aberration coefficient $C_5^*$ of 1.1 mm). Even though these aberration coefficients are the best value available in commercial instruments without an aberration corrector, the major limitation is the 3rd-order spherical aberration and the probe diameter can be at best 160 pm at $\alpha = 11$ mrad with a defocus of ~28 nm. In contrast, the residual aberrations can be the 5th-order spherical aberration ($C_5$) and six-fold astigmatism (A5) after complete aberration tuning in a CEOS hexapole-based corrector system [15, 16]. With the residual aberrations of $C_5 = 0.5$ mm and $A_5 = 1.2$ mm, the geometric-aberration limited probe size can reach to 40 pm at ~40 mrad as shown in Fig. 1 (open triangle). In the aberration-corrected condition, however, the major limitation can be the chromatic aberration and the optimum angle is reduced only to 23 mrad. Then, the optimum probe size is degraded to 85 pm from 40 pm due to the chromatic aberration. 

**Figure 2** shows the optimum angle for the overall probe in the conventional and aberration-corrected conditions summarized as a function of the probe current with the corresponding probe diameter d(59%) for the Schottky FEG [12].
about the probe optimization can be found elsewhere [12, 17].

Figure 3 shows simulated intensity distributions and extracted line profiles of the overall probes at probe currents of (a) 30, (b) 120 and (c) 500 pA in an aberration-corrected 200 kV instrument with a Schottky source. These selected probe currents are typical values for HAADF-STEM imaging, EELS analysis and XEDS analysis, respectively. The simulation was performed at optimum convergence angles for corresponding probe currents, as shown in Fig. 2. Both the intensity distributions and the profiles are normalized with the peak intensity at 500 pA. Therefore, the peak intensities at lower current conditions are correspondingly lower (i.e., ~5% at 30 pA and ~70% at 120 pA against the peak intensity at 500 pA). In the profiles, the normalized chromatic-aberration limited profiles are also plotted as dashed lines. At 30 pA, the dominant contribution is chromatic/geometric aberrations to the final probe formation. However, at higher currents for analysis applications, finite source size is the dominant factor for probe formation. Simulated d(59%) values at 30, 120 and 500 nA are 118, 152 and 220 pm, respectively.

Figure 4 shows HAADF-STEM images of Si<110> recorded at (a) 30, (b) 120 and (c) 500 pA in an aberration-corrected 200 kV J EOL JEM-2200FS STEM with a Schottky FEG at Lehigh. Intensity profiles extracted from the individual images are also inserted in Fig. 3. At 30 pA, the intensity reduction between the atomic column of the Si dumbbell reaches over 25%, which satisfies the Rayleigh criterion as described previously. The intensity reduction is slightly degraded at 120 pA, and no reduction can be observed at 500 pA. These experimental results are superimposed with the simulated d(59%) values as shown in Fig. 3.

For atomic-resolution chemical analysis, the probe optimization is the crucial factor. In addition, spatial resolution caused by the convolution of the incident probe with probe broadening must be maintained in atomic level. Since the beam broadening is strongly dependent on the specimen thickness, the spatial resolution should be evaluated as a function of the specimen thickness. In addition, since analytical signals of X-ray and energy-loss electrons are generated from the whole analyzed volume, it would be more appropriate to employ 90% of the total intensity rather than simple evaluation based on the Gaussian beam-broadening.

Advanced data acquisition and analysis procedures

As predicted above, thinner specimens are essential for atomic-resolution chemical analysis. This means that the analyzed volume is extremely restricted, and hence generated signals for atomic analysis are also limited. In addition, signal fluctuations are not completely predictable in atomic resolution analysis as shown later. Therefore, advanced approaches for data acquisition and analysis are essential for detecting such signal fluctuations from limited signals under relatively high noise in atomic resolution analysis.

Spectrum imaging (SI) has been developed to expand and improve conventional elemental mapping [21, 22], which requires prior knowledge of the specimen to set particular energy windows. In SI, a full spectrum is continuously recorded at each pixel. Thus, the SI method offers post-acquisition treatments of elemental maps including regular spectral-processing methods, such as background subtraction and signal deconvolution. Therefore, it is possible to map out unexpected minor elements that are not even considered for mapping beforehand if the signals from such minor elements are successfully identified. However, for characterization of elemental fluctuations in atomic resolution, elemental mapping including SI in STEM still suffers from limited signals. Furthermore, there might be many variables even in a single SI dataset: some could be expected and others are totally unaware. It is essential to find out those variables in the dataset, which can be performed by employing multivariate statistical analysis (M SA).

The MSA method is a useful family of statistic-based techniques to analyze large datasets. The general concept of MSA is to reduce the dimensionality of an original large dataset by finding a minimum number of variables that describe the original dataset without losing any significant information [e.g., 23, 24]. This approach is useful for large, complicated data such as XEDS or EELS SI datasets.
which has been successfully demonstrated by Koluta et al. [25].

For example, a STEM-EELS SI dataset was taken from SrTiO$_3$ in an aberration-corrected JEM-2200FS instrument at 200 kV. A HAADF-STEM image from a SrTiO$_3$ thin specimen is shown in Fig. 6(a) [26]. The bright and slightly darker spots in the image correspond to the Sr and Ti-O columns in the [001]-projected perovskite structure, respectively, and an EELS-SI data was acquired from the region indicated as a dashed square with $13 \times 13$ pixels for a dwell time of 0.1 s per pixel. Two spectra at the Sr and Ti-O column positions extracted from the SI are compared in Fig. 6(b). Although the spatial difference spectrum (Fig. 6c) between the spectra from the Sr and Ti-O columns shows a reduction in the vicinity of the Sr M$_{2,3}$ edge and an enhancement in the Ti L$_{2,3}$ edge, both spectra seem almost identical and it would be harder to distinguish one spectrum from another. To confirm the difference in the spectra between the Sr and Ti-O columns, MSA was applied to the dataset. By applying the MSA method, the SI dataset can be decomposed to loading and score matrices: the former contains spectral feature uncorrelated to other row information and the later represents the spatial amplitude of the corresponding loading spectrum. In Fig. 7, pairs of the loading spectrum and the corresponding score image of the (a) first and (b) second components are compared. The most significant component in the dataset is always the average (i.e., the average information is repeated at every pixel), and hence the loading spectrum of the first component represents the average spectrum of the SI dataset. Sr M$_{2,3}$ and Ti L$_{2,3}$ edges can be seen in this SI dataset. Any component after the first component indicates the difference from the average. Therefore, loading spectra after the first component contain positive and negative regions. The brighter regions in the score image of second component correspond to the Ti-O atom.
ic-columns, where the Ti L_{2,3} edge signal is more enhanced and the Sr M_{2,3} edge signal is reduced. This second component agrees well with the spatial difference spectrum shown in Fig. 6(c), i.e. the Ti L_{2,3} edge signals are clearly at the Ti-O columns in SrTiO_3. Therefore, the signal fluctuation in different atomic-columns is real and essentially one of the dominant features repeated a number of times in the dataset.

In addition, MSA may reveal unexpected features in the dataset as well. Figure 8 shows another example of the MSA application to atomic-column EELS SI dataset taken from a [0001]-projected Si_3N_4 specimen by an aberration-corrected JEM-2010F STEM at 200 keV [27]. The SI dataset was recorded with 50×45 pixels and 670 energy-channels (with binning 2) using a Gatan Enfina spectrometer for a dwell time of 20 ms. The first two components extracted from the dataset by MSA are shown in Fig. 8. Again, the average is the most frequently repeated information in the dataset (component #1) as shown in Fig. 8a. In the component #2 (Fig. 8b), the brighter regions in the score image correspond to the Si atom positions in the six-fold ring. Surprisingly, this enhancement at Si atom positions occurs not at the Si L_{2,3} edge, but after the Si L_{1} edge as shown in the spectrum of component #2. This resolution difference in a different energy-loss region can be due to the delocalization-effect dependence on the offset energy from the ionization edge, as recently discussed by Kimoto et al. [28]. Such unique correlations of spectral features with specific spatial locations might not be identified accurately unless these correlations are well known prior to data acquisition/analysis. However, by applying MSA, these unexpected features can be automatically revealed, based on numbers that the features are repeated.

After dominant features are identified in the dataset, the original dataset can be described with a limited number of the featured components, and then random noise that is not repeated at all can be efficiently removed from the dataset. The data reconstruction without random noise components results in the enhancement of weak signals in SI datasets. In the SI dataset from atomic-resolution Si_3N_4, the noise reduction was applied by subtracting noise components. Figure 9 compares Si L_{2,3} edge (a) and Si L_{1} edge (b) maps extracted with background subtraction from the original and MSA-reconstructed datasets. This comparison of maps from the original and reconstructed datasets clearly demonstrates the efficient removal of the noise. The reconstructed maps from both the Si L_{2,3} and L_{1} edges maps show Si atom arrangement with a six-fold ring. The Si atom arrangement in the six-fold ring is more clearly pronounced in the Si L_{1} map, and the individual Si atomic columns can be clearly distinguished, as expected from component #2 shown in Fig. 8(b).

Recently, one of the authors (MW) has developed the MSA software package as a series of plug-in for Gatan DigitalMicrograph Suite [29]. This particular MSA plug-in package has been applied for various SI datasets acquired by EELS and XEDS [3, 5, 29-32]. This package is now available through HREM Research Inc. Further information can also be found at the company’s web site [33] or the author’s web site [34].

### Applications of atomic-resolution chemical mapping in the JEM-ARM200F

**STEM-EELS based chemical imaging**

For atomic-level analysis, the STEM probe must be positioned above individual atomic column sites during acquisition, which requires relatively long-term instrumental and environmental stabilities. Two examples of atomic-resolution EELS imaging shown above were taken from the 1st generation JEOL aberration-corrected STEMs, which were constructed by adding the CEOS correctors to existing microscope columns. The newly developed JEOL JEM-ARM200F aberration-corrected STEM instrument is designed to perform the atomic-level chemical analysis with improved instru-
mental stabilities. Some of the major improvements of the JEM-ARM200F are: (i) significantly reduced mechanical instabilities by optimizing the column stiffness to accommodate the probe corrector; (ii) efficient suppression of external influences, such as stray electro-magnetic fields, temperature/pressure fluctuations, air flows and sound vibrations, by the incorporation of a heat insulation shield, a magnetic shield and an external mechanical cover; and (iii) reductions in instabilities of the accelerating voltage, objective/condenser lens currents and deflector coils by a factor of 2 from the first generation instruments[35]. The spatial drift rate in the new instrument is 0.5 nm/min.

The improved performance for atomic-resolution analysis in the newly developed JEM-ARM200F is shown in Fig. 10, as an example. An HAADF-STEM image from an interface in a LaMnO₃/SrTiO₃ multilayer thin-film is shown in Fig. 10(a). The bright and slightly fainter spots appearing in this HAADF-STEM image correspond to heavy atomic columns of La or Sr and to Ti-O or Mn-O columns in the perovskite structure, respectively. An EELS Si data was acquired from the same field of view with 186×26 pixels and 1350 channels for a dwell time of 0.1 s using a Gatan Enfina spectrometer. After applying MSA, elemental maps were extracted by power-low background subtraction. From the extracted elemental maps, two RGB color-overlay images were constructed as shown in Fig. 10(b, Red: Ti L₂,₃, Green: Si L₂,₃, Blue: O Kα).

Fig. 9 Comparison of characteristic signal maps of (a) Si L₂,₃ and (b) Si L₁ edges extracted from the original and MSA-reconstructed SI datasets of Si₃N₄ with background subtraction [27].

Fig. 10 (a) HAADF-STEM image from a LaMnO₃/SrTiO₃ interface. (b) RGB color-overlay image of SrTiO₃ and (c) RGB color-overlay image of LaMnO₃, obtained by the EELS approach (Specimen courtesy of Drs. Maria Varela and Ho Nyung Lee at Oak Ridge National Lab.) [36].
Sr M 2,3 and Blue: O K) and 1c, Red: Mn L 2,3, Green: La M 5 and Blue: O K), which represent SrTiO 3 and LaMnO 3 layers, respectively [36]. Elemental distributions can be obtained from much larger fields of view, which is only possible in the improved stability in the JEM-ARM 200F. In addition, at individual atomic columns can be clearly distinguished. Especially the Ti distribution is terminated at the LaMnO 3/SrTiO 3 interfaces relatively sharply, whereas the Mn distribution seems diffused toward SrTiO 3 layers.

**STEM-XEDS-based Chemical Imaging**

As shown above, atomic-resolution EELS imaging is routinely applicable in aberration-corrected STEM with better resolution and improved stability [e.g., 3-5]. For X-ray analysis, such atomic-column analysis or even atomic-column mapping has not even been attempted, mainly because atomic-resolution STEM images are not obtainable with the higher probe currents (and consequent large probes) required for X-ray analysis in conventional STEM instruments due to poorer signal collection efficiency as discussed above (~100 times worse than EELS). However, since the aberration correction makes it possible to reduce the incident probe size while maintaining higher currents, it may be feasible to perform atomic-column X-ray analysis. In fact, the spatial resolution of X-ray analysis is improved to ~0.4 nm [6] and the detectability limit may approach a few atoms [17], which implies atomic-level analysis/mapping by X-ray analysis is feasible in aberration-corrected STEM.

Using the JEM-ARM 200F microscope, GaAs was analyzed at an atomic scale by the XEDS approach [36]. **Figure 11** (a) shows an atomic-resolution HAADF-STEM image of [001]-projected GaAs. In this projection, the Ga and As layers are separated, as shown schematically in **Fig. 11** (b) (drawn by Vesta [37]). Since the difference in the atomic number is only two between Ga (31) and As (33), the Z-contrast between two elements may not appear unless a very thin specimen is observed. An XEDS SI dataset was acquired from the selected squared region in the aberration-corrected STEM. By applying MSA, unexpected information hidden in a Si dataset can be revealed. In addition, random noise in the datasets can be efficiently reduced by MSA. This combination of SI with MSA is very useful for analysis of atomic-column datasets, where unexpected signal correlations might be hidden over relatively high random noise due to the short acquisition time and the small analytical volume, as shown in several examples. It is now possible to perform atomic-resolution chemical imaging by STEM-EELS and STEM-XEDS methods in the latest aberration-corrected instrument, such as the JEM-ARM 200F. In near future, the atomic-resolution chemical imaging approach would be routinely available for materials characterization.

**Summary**

In this manuscript, the optimum probe formation in aberration-corrected STEMs was reviewed for atomic-resolution chemical analysis by EELS and XEDS. The new approaches for data acquisition by SI and for data analysis via MSA were discussed as well. By applying MSA, unexpected information hidden in a Si dataset can be revealed. In addition, random noise in the datasets can be efficiently reduced by MSA. This combination of SI with MSA is very useful for analysis of atomic-column datasets, where unexpected signal correlations might be hidden over relatively high random noise due to the short acquisition time and the small analytical volume, as shown in several examples. It is now possible to perform atomic-resolution chemical imaging by STEM-EELS and STEM-XEDS methods in the latest aberration-corrected instrument, such as the JEM-ARM 200F. In near future, the atomic-resolution chemical imaging approach would be routinely available for materials characterization.

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**References**


Fig. 12 (a) HAADF-STEM image of the [001]-projected GaAs simultaneously recorded during SI acquisition; a set of a Ga map, an As map and a color-overlay map of K$_\alpha$ X-ray lines (b), L X-ray lines (c) and EELS L$_{2,3}$ edges (d) [36].
Application of a Helium-Cooled Cryo-Electron Microscope for Single Particle Analysis

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Introduction

Cryo-electron microscopy (cryo-EM) is a powerful tool in structural biology for a broad range of targets and resolutions. Electron crystallography can yield maps with better than 2 Å resolution from two-dimensional (2D) crystals of membrane proteins [1]. Tubular crystals of membrane proteins are grown during the 2D crystallization trials of membrane proteins, and helical reconstruction can provide the three-dimensional (3D) structures at atomic resolution in those cases [2]. The resolution of single particle analysis of protein complexes has been improving [3], and an atomic model was recently proposed from a 3D structure determined by this method [4]. While all three of these methods can determine the atomic model from the 3D reconstruction, single particle analysis does not require crystals for the structural determination, and therefore it is considered to be the most general method. In addition, because the particles in different states can be distinguished by image classifications in the single particle method, we can analyze the structures in an equilibrium of different states. Thus, the range of targets for high-resolution structural analysis can be expanded by single particle analysis.

The principle obstacle for high-resolution structural analysis in electron microscopy is irradiation damage of the biological specimen and cooling the specimen to cryogenic temperatures can reduce the effects of irradiation damage. To achieve higher resolution structures by reducing the irradiation damage, even in single particle analysis, a new cryo-electron microscope with a liquid helium-cooled stage was developed, and we utilized it in two studies using single particle analysis. For the application, we slightly modified the sample preparation technique developed for the high-resolution image collection from the tubular crystals, using the liquid helium-cooled stage. The first application was to determine the structure of the GroEL-GroES-substrate complex from Thermus thermophilus. We observed a density corresponding to the folding substrates inside the complex. The second application was the three-dimensional reconstruction from tubular crystals of a membrane protein, human erythrocyte band 3. Iterative helical real-space reconstruction, which is a modification of single particle analysis for tubes with helical symmetry, was used for this purpose. These two examples clearly show that the three-dimensional structures of a broad range of targets can be analyzed by single particle analysis.

Fig. 1 The cryo-electron microscope, equipped with a liquid-helium cooled stage, for single particle analysis. The accelerating voltage of the field emission gun is 200 kV, and it is equipped with an 8K × 8K CMOS camera.
for single particle analysis using the liquid-helium cooled stage, and the resulting structure we obtained using the protein complexes from Thermus thermophilus. In addition, we recently applied the single particle analysis to the tubular crystals of a membrane protein, and those results will also be discussed.

**Helium-cooled cryo-electron microscope for single particle analysis**

While the new JEOL cryo-electron microscope equipped with a liquid-helium cooled stage for single particle analysis has almost the same cryo-stage as those of the cryo-electron microscopes used for electron crystallography [11], the accelerating voltage of the field emission gun is 200 kV, and it is equipped with a CMOS camera with pixel sizes of 8k by 8k (TemCam-F816, TVIPS, Gauting, Germany). The advantage of the 8K camera for single particle analysis is clear. We can collect more particle images from one exposure, and therefore particle analysis is clear. We can collect more particle images from one exposure, and therefore the data collection is more efficient. The choice of the accelerating voltage of 300 kV, which we normally use for electron crystallography, becomes better at 200 kV, as compared with the 4K camera. The point-spread function of the camera is related to the accelerating voltage, where

$$\text{Contrast} = \frac{|A_{\text{avg}} - A_{\text{bkg}}|}{\text{Std}_{\text{bkg}}}$$

where $A_{\text{avg}}$ is the average of the pixel values in the particle images, $A_{\text{bkg}}$ is the average of the pixel values in the background area, and $\text{Std}_{\text{bkg}}$ is the standard deviation of the background area. The calculated values are 0.11 and 0.045 for 200 and 300 kV, respectively, and thus the image contrast is much better at 200 kV than at 300 kV. Since the contrast of the cryo-images is very weak, the improvement in the number of electrons for the imaging could clearly enhance the image contrast.

**Sample preparation for helium-cooled cryo-electron microscopy**

The preparation of the EM grids to yield good images for image processing, using the liquid helium-cooled stage, is also important. The significant difference between the nitrogen and helium temperatures lies in the conductivity of the specimen. Since the resistance of carbon is significantly increased at 4 K, some care must be taken to minimize the beam-induced movement by specimen charging. The procedures described here were developed for the high-resolution image collection from tubular crystals of nicotinic acetylcholine receptor [13], and we used the techniques with only slight modifications. Electron irradiation usually results in charging of biological specimens, which causes beam-induced movement. The inelastic scattering causes the emission of secondary and Auger electrons, which render the specimen positively charged. A clean, 50 μm diameter gold foil objective aperture can be used to emit electrons to neutralize the positive charge.

The preparation of the high conductivity carbon film also important to minimize the beam-induced movement. When we used Quantifoil R1/4 holey grids (Quantifoil Micro Tols GmbH, Jena, Germany), we deposited carbon (99.9999% purity) onto the grids, with minimal sparking, in a vacuum of $<10^{-5}$ mbar during deposition, after washing the Quantifoil grids by immersing them in purified water over several hours. After the deposition, the grids were washed again by immersing them in ethyl acetate for 20 minutes. The carbon-coated grids were then irradiated by 100 kV electrons with a total dose of over 100 e⁻/Å² for more than 3 hours. This pre-exposure could improve the conductivity of the carbon.

Finally, symmetrical imaging conditions, with the beam entirely covering the hole all the way to the carbon, were used. However, even after these considerations, our ability to obtain good images was still marginal. To evaluate the images, we calculated the Fourier transforms from the center area of the hole. As shown in Figure 2, the Fourier transforms calculated from a good image show clear and symmetrical...
were determined by analysis. The 2D alignment and classification pictures, and performed the single particle which were selected as GroEL-GroES complexes. Thus, the classification of several different structures and the strates are folded by GroEL. However, the classification results were published using GroEL, and those results were published which postulates that there is only one transport site, which faces either intracellularly (inward-open form) or extracellularly (outward-open form). Conformational changes between these forms only occur if a substrate is bound to the transport site. The 3D structure of the outward-open form, which consists of at least two subdomains, is consistent with this model, but a higher resolution structure is required to determine the relationship between the structural features revealed here and the function of band 3.

**Application of single particle analysis to the tubular crystal of a membrane protein**

The single particle method can be applied not only to protein complexes but also to various samples. For example, the 3D structures of the tubular crystals of membrane proteins can be analyzed by modifying this method. Iterative helical real-space reconstruction (IHRSR) uses single-particle image analysis, in combination with imposed real-space helical symmetry, to allow the effective analysis of tubular crystals with such properties as poorly ordered helical symmetry, bent tubes, or low signal-to-noise ratios on electron microscopy images. Here, we show the 3D structure of the membrane protein band 3 in an inhibitor-stabilized, outward-open conformation at 18 Å resolution, which was determined by this method.

Erythrocyte band 3 (anion exchanger 1, or AE1) mediates the electroneutral exchange of ions such as chloride and bicarbonate across the erythrocyte plasma membrane. Band 3 contains two functionally independent cytoplasmic and membrane domains. The cytoplasmic domain functions to anchor the cytoskeleton to the plasma membrane, while the membrane domain allows anion exchange. We purified the band 3 protein with the anion transport inhibitor 4,4'-dithiothreitol (DTT). Two H2DIDS molecules, which act as acidic folding substrates such as H2DIDS, reportedly stabilized band 3 in the outward-open form. Using the purified H2DIDS-bound, outward-open membrane domain of band 3 (hB3MD), and a dialysis procedure, we obtained tubular crystals with a diameter of 37 nm, and applied IHRSR to the crystals.

**Figure 4** shows the overall 3D map of the band 3 dimer, still. Two H2DIDS molecules, which form a dimer, are enclosed within blue and green boxes. All of the hB3MD dimers in the tubular crystals are oriented in the same direction relative to the tube axis and appear to be in close contact with each other. An immunoelectron microscopy analysis using 2A8 IgG antibodies revealed that the outer and inner surfaces of the tubular crystal corresponded to the intracellular and extracellular portions of hB3MD, respectively. The membrane domain of band 3 is thought to consist of several subdomains, because a projection image of the 3D map shows a 2.5-fold reduction in the size of the membrane domain, which shows density only in the upper part of the crystal. The membrane plane showed two high-density regions, suggesting that the domain is composed of at least two subdomains. However, it is currently not possible to determine which segment of the molecule interacts with each subdomain. The anion transport mechanism of band 3 has been explained by a "ping-pong" model, which postulates that there is only one transport site, which faces either intracellularly (inward-open form) or extracellularly (outward-open form). Conformational changes between these forms only occur if a substrate is bound to the transport site. The 3D structure of the outward-open form, which consists of at least two subdomains, is consistent with this model, but a higher resolution structure is required to determine the relationship between the structural features revealed here and the function of band 3.

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**References**

Fig. 3 The overall structure of the GroEL-GroES-substrate complex. (a) Side view of the 3D map, and the fitted atomic model. (b) Comparison of the empty chaperonin complex from *E. coli* with the native complex from *Thermus thermophilus*.

Fig. 4 The 3D image reconstruction of the hB3MD tubular crystal. (a) Side view of the tubular crystal. Two molecules in a possible dimer are enclosed in blue and green boxes. (b) The intracellular surface of a unit cell containing an hB3MD dimer. (c) The 3D map of an hB3MD dimer, viewed in the direction parallel to the tube axis. (d) Projection image of the 3D map from the intracellular side. The two high-density regions are indicated by solid and dashed red circles, to suggest the presence of two subdomains.

Ultrahigh-Resolution STEM Analysis of Complex Compounds

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Introduction

Quantitative determination of local structures, including how dopant elements distribute within the materials, has been one of the challenging issues of electron microscopy. In this regard, scanning transmission electron microscopy (STEM) indeed provided a breakthrough with its significant atomic-number dependent contrast, termed Z-contrast [1], which is able to show up even the single atom embedded in a solid. Besides, STEM enables the spectroscopic analysis at very small scale; local measurements of energy-dispersive x-ray spectroscopy (EDXS) and electron energy loss spectroscopy (EELS) are possible by locating the atomic-sized electron probe on the regions of interest. Owing to recent developments of an aberration corrector for the beam-converging lens, STEM is now capable of electron beam with sub-Ångstrom scale, which has remarkably improved its achievable resolution. In this article, we briefly describe some of our recent results to demonstrate the powerful use of the ultrahigh-resolution STEM for the analysis of complex compounds, including long-period modulated and aperiodic quasicrystalline structures.

STEM Experiment

STEM observations were performed by the JEM-A R M 200 F (Cs-corrected 200 kV STEM/TEM, equipped with a Schottky-emission electron gun) and by the R005 microscope (Cs-corrected 300 kV STEM/TEM, equipped with a (cold) field-emission electron gun). The latter 300 kV-STEM/TEM was developed under a JST-CREST project "Development of the 0.05 nm-Resolution (R005) Electron Microscope" (Leader, Prof. Takayanagi). The minimum full-width half-maximum (FWHM) of the STEM probes are calculated to be approximately ~0.9 Å and ~0.5 Å for 200 kV and 300 kV, respectively. Both STEM indeed provide sub-Ångstrom resolution [2-4], which are demonstrated by imaging the dumbbell atoms separated by less than 1 Å (they occur for the diamond-based structures when viewed along the [110] (or even higher index direction)).

Direct determination of a long-period modulated structure in a Mg97Zn1Er2 Alloy

Mg alloys containing a small amount of Zn and RE (RE: Y and rare-earth atoms), e.g., Mg97Zn1RE2 (at.%) alloys reveal excellent mechanical properties with high yield strength over than ~500 MPa and elongations better than ~3% at room temperature. One of the key microstructural features is formation of a novel type of long-period ordered (LPO) structure [5], which is long-period chemical-ordered as well as stacking-ordered. There exist several stacking polytypes denoted as 18R, 14H, 10H, 24R, all of which are composed of a common structural unit represented by local A B C A stacking where B- and C-layers are significantly enriched by Zn and RE (these particular layers are denoted as B' and C' layers hereafter). It is found that a number of weak satellite spots appear in the diffraction pattern taken along the stacking direction (c-axis), suggesting that a further ordering within the close-packed B' and C' layers with a six-times modulation along <1210>occurs. Using Cs-corrected STEM, we have investigated the detailed chemical order in the 14H-type LPO structure in the Mg97Zn1Er2 alloy. Note that Er is a large Z element (Z=68) compared to the other RE (Mg: Z=12, Zn: Z=30), so that individual Er atoms can be detected through Z-contrast even they are embedded in the complicated structure.

Cs-correction effects appear to be quite significant for the direct imaging of the dense-packed atomic structures, as obviously demonstrated in Fig. 1 (a) and (b). After Cs-correction, the fundamental reflections of 1210x are clearly reproduced in the FFT pattern by accompanying a number of extra weak spots. Concerning that the Z-contrast image reflects a significantly enhanced chemical-potential differences, it can be deduced that the long-period modulation is predominantly due to a concentration modulation along <210>. To investigate its average features, we construct auto-correlation map from the observed image of Fig. 1(b), and the result is shown in Fig. 1(c). All the atomic sites are successfully reproduced in the auto-correlation map, and the average modulations can be directly derived from the intensity distributions. The short-range Er configurations should be related to the most intense spots in the map, showing that the Er-Er distance is at the second-nearest sites. This is reasonably attributed to a D03-type short-range order, which is in fact frequently observed in the Z-contrast image of Fig. 1(b). By referring further details of the intensity distributions, we are able to construct an average model of the complex long-range modulated structure, as shown in Fig. 1(d).

Local chemistry of a hydrogen-storage (La, Y)5Ni19 complex compounds

LaNi2 (3 ≤ x < 5) complex compounds with a block-stacking superstructure have attracted increasing attentions due to their reasonably good hydrogen-storage properties at ambient conditions [6,7]. The block-stacking superstruc-
tures are constructed by stacking the "structural blocks", which are represented by Haucke-unit (LaNi5) and Laves-unit (LaNi2). From the previous studies, it is shown that the hydrogen-storage properties of the block-stacking compounds are basically understood by different hydrogenation behaviors of the local Laves-unit/Haucke-unit within the superstructures. For controlling their compositions by the element substitutions to form the (La, X)Ni compounds, it becomes important to understand their favorable substitution sites and how they alter block-unit structures. These local issues are, of course, closely related to the macroscopic hydrogen-storage properties.

Here we describe a change of local chemistry during the hydrogenations of the Y-doped (La0.6Y0.4)5Ni19 block-stacking compound. This material is able to store the hydrogen up to ~1.1 H/M (mean number of hydrogen atoms per a constituent-metal atom), but almost the half of the stored-hydrogen will be still retained (~0.5 H/M) even after the discharging process. Fig. 2 (a) and (b) show the atomic-resolution Z-contrast images of the (La0.6Y0.4)5Ni19 compounds, taken from the specimens before and after a hydrogen charge-discharge process. It is clearly seen that an anisotropic lattice expansion along the c-axis occurs only at the Laves (L) -unit, as shown by L" in Fig. 2(b), suggesting that the retained-hydrogen are mostly captured in the original L-unit to transform it into the local L" hydrides. In the L" hydride layer, the Ni atoms originally located at the center in the L-unit are found to disappear during the hydrogenations (see the positions indicated by arrowheads in Fig. 2 (a) and (b)), revealing significantly dark Z-contrast as confirmed in the average intensity profiles (Fig. 2(c)). Interestingly, it is also noticed that the profile shows La/Y concentration modulations along the c-axis, which have been induced during the hydrogenation process.
at room temperature. This is also confirmed by STEM-EDXS, showing significant deficiency/enrichment of Ni/Y at the L'' hydride layer, respectively (Fig. 2(d); note that the Ni concentration seems to modulate along the c-axis, but it could simply due to a delocalization effect. We just draw the conclusion that the local Ni deficiency at the L'' layer is reasonably confirmed by STEM-EDXS with a practical spatial-resolution ~1 nm). Local hydrogen concentration can be successfully evaluated from the shift of the plasmon peaks (ΔEp) observed between the L and L'' layers (Fig. 2(e)), estimating the possible number of hydrogen atoms to be 7~8 based on a simple free-electron approximation [8,9] and the local composition of the L'' layer as being (Y,La)2Ni3H8. This is confirmed to be fairly reasonable values that can account for those determined by the macroscopic chemical analysis. From these systematic analyses by STEM, the change of local chemistry during the hydrogen charge-discharge process is schematically summarized in Fig. 2(f).

**Direct determination of a complex quasicrystalline structure Al70Mn17Pd13**

Quasicrystals are aperiodically long-range ordered solids that exhibit rotational symmetries incompatible with conventional periodic lattice order. Their structure is often described according to a hyperspace crystallography, which interprets the quasicrystal as a periodic structure embedded in a hyperspace. This mathematical recipe enables to calculate the diffraction intensity of any quasicrystal model structures, and accordingly the quasicrystal structures can be, in principle, determined by the x-ray diffraction analysis along the similar manner for periodic crystals.

Al-Mn-Pd alloys form a stable decagonal quasicrystal, a planar realization of the quasiperiodic order. Its structure had been intensively studied by single-quasicrystal X-ray diffraction analysis [10] as well as high-resolution phase-contrast electron microscopy [11,12], which led to the established model structure that reasonably satisfies both the observations.

![Atomic-resolution Z-contrast STEM images obtained from the (La0.6Y0.4)5Ni19 block-stacking compound; (a) original and (b) after the hydrogenation process. These images are taken by JEOL JEM-ARM200F. (c) HAADF/Z-contrast intensity profiles along the c-axis, obtained by integrating over the box regions A-B in (a) and C-D in (b). L'' positions are indicated by arrowheads. (d) EDXS intensity profiles along the c-axis for Ni (red) and Y (blue), where the L'' positions are indicated by arrowheads. These are taken using an electron beam with the size of approximately ~3 Å (current density >~100 pA/cm²). (d) Low-loss EEL spectra (< 70 eV) obtained from the Laves- and Haucke-units of the original and hydrogenated (La0.6Y0.4)5Ni19 compounds, using the smallest electron probe (~1.0 Å). The origins of the spectra positions are corrected by referring the Ni-M edge (68 eV), which appears due to delocalization effects at relatively low-energy regions, even though there is no Ni atoms at the L'' layer. Significant peak shift is only observed between the original L- and L''-units, the amount of shift is estimated to be ~ 0.6 ± 0.1 eV after the peak-fitting (inserted). (f) Schematic drawing of the local structural change during the hydrogenation process.
However, the ultrahigh-resolution Z-contrast STEM imaging has unveiled the local details that immediately forces to modify the existing model, see Fig. 3 (a) and (b). The observed Z-contrast distribution (Fig. 3(a)) cannot be reproduced by the simulation based on the model structure proposed by X-ray analysis [2] (Fig. 3(b)), forcing to modify the local chemical order of Al/Mn/Pd. It should be emphasized here that all the atomic sites, which are densely distributed within the complex quasicrystalline structure and occupied by the atoms of large atomic-number differences (Al: Z=13, Mn: Z=25, Pd: Z=46), are clearly imaged in Fig. 3(a) even under the Z-contrast condition. This demonstrates a remarkable performance of the present 300kV-STEM. As exemplified by the decagonal clusters, the improved structure now fairly well reproduces the observed Z-contrast, as shown in Fig. 3(c). We are now attempting further modifications to describe the entire structure of the decagonal Al70Mn17Pd13, with the aid of STEM-EELS to identify details of Mn/Pd occupations at each atomic site. The present results strongly demonstrate again the powerful use of STEM for the study of aperiodic quasicrystal structures [13-15].

Summary

We have demonstrated the remarkable performance of the state-of-the-art STEM, based on its successful application for elucidations of the multi-component complex structures. At the age of computer-controlled aberration-corrected microscopy, for TEM/STEM experiments special master-hand techniques are not required any longer, and the sub-A resolution is now routinely and practically available for many types of materials. Given with increasing opportunities for highly quantitative/precise microstructure analysis, we expect that the modern STEM will provide a considerable number of breakthrough results – definitely a new era of microscopic science!

References

Development and Applications of a Frequency Modulation Atomic Force Microscope for High-resolution Imaging in Liquids

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Introduction

The dynamic mode atomic force microscope (AFM) using the frequency modulation (FM) detection technique [1] has been widely used for high-resolution imaging in ultrahigh vacuum (UHV) environments with the aid of a high Q-factor of the cantilever [2]. In fact AFM imaging in air, where the instrumental setup can be generally much simpler, is more suitable for various, practical applications. However, the true atomic/molecular-resolution imaging by AFM in air is extremely difficult. A major difficulty in achieving such resolution in air AFM is that the specimen surface and/or the AFM tip can be damaged by the strong adhesion force acting between the tip and the surface due to a thin water layer of the surface. AFM imaging in liquid is a possible way for avoiding the adhesion problem and for the high-resolution imaging. High-resolution imaging with FM-AFM in liquid is again very difficult because of a large decrease in the Q-factor due to the hydrodynamic damping in liquid. Recently, several high-resolution images of mica surfaces and organic molecules including biomolecules have been successfully reported using FM-AFM in liquids [3]. The success of high-resolution FM-AFM imaging in liquid encourages us to expand the applications of FM-AFM to new research fields.

In this study we improved a commercial AFM, JSPM-5200, and succeeded in obtaining high-resolution images of polypropylene sheet, Au thin films and DNA molecules in liquids. These results show that our improved FM-AFM has the capability of high-resolution imaging in liquids. This FM-AFM is expected to be used for a wide variety of industrial and scientific applications.

Discussion

A sufficient noise reduction in both cantilever deflection sensor and FM detection circuit is necessary for high-resolution imaging in liquids [4]. A commercial AFM (JSPM-5200) using the optical beam deflection method, as shown in Figure 1, was modified. Figures 2 show photos of the improved AFM. To decrease the mode hop and the interference noises in the optical detection system, the coherence of the laser beam used for the cantilever deflection sensor was suppressed by adding a radio frequency modulation signal to the laser diode. Furthermore, the optical setup of the cantilever was also optimized, as shown in Figure 3. As a result, the noise density of the improved deflection sensor was reduced to 29 fm/√Hz in water at a laser power of 1 mW, which is compliant to class II for the classification of performance standard for light-emitting products. This value is much smaller than those obtained with conventional instruments (typically 500-1000 fm/√Hz). In addition, the noise of the phase-locked loop (PLL) circuit in the FM detector was also reduced while the frequency bandwidth was increased by the field programmable gate array (FPGA), as shown in Figure 4. The FM detector noise was reduced to 6 mHz/√Hz and the frequency bandwidth was expanded to 6 kHz. As a result, stable FM-AFM imaging in liquids can be conducted even with a small oscillation amplitude of less than 0.2 nm. Moreover, the SPM head was placed in a vacuum thermo-stabilized chamber to reduce the thermal drift as shown in Figure 5. As a result, the thermal drift was kept at less than 1 nm/min in air for a sufficiently long time in an ordinary room where several people were walking around. Thermal drift in liquid was a little larger than in air because of the influence of the liquid evaporation. Consequently, sub-nanometer resolution images of muscovite mica surfaces in a buffer solution were successfully obtained by FM-AFM mode using our improved AFM with a small oscillation amplitude of 0.5 nm, as shown in Figure 6.
Fig. 1 JSPM-5200. The modified part is shown in Fig. 2.

Fig. 2 High-resolution AFM for imaging in liquid.

Fig. 3 Schematic diagram of the AFM head.

Fig. 4 The block diagram of the FM detection electronics.

Fig. 5 Schematic diagram of the vacuum thermo-stabilized chamber.

Fig. 6 FM-AFM image of a muscovite mica surface in a buffer solution (0.1mol/L KCl). Scan size is $5 \times 5$ nm$^2$. 
Using the improved AFM, we imaged surfaces of a polypropylene sheet and annealed Au thin films on a mica surface in a liquid. A highly doped n-Si cantilever (Nanoworld: NCH) was used as the force sensor. The peak-to-peak amplitude of the cantilever oscillation was set at a value ranging from 0.5 to 1.0 nm. First, the polypropylene sheet was observed in UHV. The results are shown in Figures 7. The polypropylene chains are clearly resolved, as shown in Figure 7(a), on a (120) crystal facet in a magnified image of a fiber circled in Figure 7(b) [5]. Figures 8(a) and (b) show FM-AFM images of the same polypropylene sheet taken in a buffer solution (0.1 mol/L KCl). An island composed of some terraces was observed in tangles of polypropylene fibers (Fig. 8(a)). The periodic structure corresponding to the molecular array was also observed on a surface of the terrace (Fig. 8(b)), whose spatial resolution seems to be almost comparable to the one obtained in UHV. As shown in Figure 8(c), a high-resolution image was also obtained in air. However, the cantilever oscillation had to be five times larger than in the liquid to avoid the cantilever adhesion to the surface, which could have disturbed imaging of the fine structures of the sample.

Figures 9(a) and (b) show FM-AFM images of an annealed Au thin film on mica in the buffer solution (0.1 mol/L KCl). Usually, the atomic scale images of the Au thin film surface can be obtained using UHV-STM or Electrochemical STM. In this experiment, the herringbone structure on a terrace was successfully observed even in liquid, as shown in Figure 9(a). Furthermore, the periodic structure corresponding to the atomic array could be visualized with the size of 3 × 3 nm² on a flat area of the surface as shown in Figure 9(b).

We also successfully obtained high-resolution images of a highly orientated pyrolytic graphite (HOPG) surface in pure water. While the atomic scale images of the HOPG surface have been obtained using FM-AFM in UHV, it is pointed out that the topographic signal is quite small because of the relatively weak interaction force between the tip and the HOPG surface [6]. Figure 10 shows an FM-AFM image of the HOPG surface taken in pure water. The peak-to-peak amplitude of the cantilever oscillation was set at 0.2 nm. The periodic structure was visualized corresponding to the periodic structure of the surface, as shown in Figure 10. Thus we succeeded in obtaining high-resolution images of HOPG by FM-AFM in liquid as well as in UHV.

With this advanced technique, we also imaged DNA tiles, in which several numbers of DNA strands were self-assembled and packed into two-dimensional patches [7,8]. There have been several studies on high-resolution imaging of DNA molecules in UHV [9]. However, high-resolution imaging of DNA molecules in liquid is strongly required in biological studies. This is because the structure and the properties of the DNA are stable only in physiological solution. The peak-to-peak amplitude of the cantilever oscillation was set at 1.0 nm. Figures 11(a) and 11(b) show a design of a DNA tile used in this experiment and an FM-AFM image of the DNA tiles on mica in a buffer solution, respectively. As shown in Figure 11(b), pairs of double strands aligned in parallel were
Fig. 11 (a) The design of a DNA tile used in this experiment, (b) FM-AFM image of the DNA tile on mica in a buffer solution. The periodicity of DNA obtained in a previous UHV observation [9] was 4.2 nm. This difference in the periodicity is probably caused by the drying process in the specimen preparation for UHV observation.

Conclusion

We succeeded in improving our commercial AFM for high-resolution imaging of various materials in liquids. With this AFM, high-resolution images of a polypropylene sheet and an Au thin film were reproducibly obtained in liquid. The spatial resolution in these images was comparable to that in the typical images of the same samples taken in UHV. Furthermore, the double strand structure of the DNA double helix was observed in liquid, which had not been obtained in UHV. The present success in obtaining high-resolution images of the several sample surfaces in liquid indicates that the liquid environment is a quite suitable and promising environment to perform high-resolution AFM imaging. Thus it can be the alternative to the UHV environment for high-resolution FM-AFM observation.

Acknowledgements

We wish to express our appreciation to Dr. Furuta at Kobe Advanced-ICT Research Center for supplying DNA.

References

[8] DNA tiles used in the liquid FM-AFM observation was synthesized and supplied by Dr. Ken’ya Furuta of Kobe Advanced-ICT Research Center, NICT, Kobe.
Introduction
It is widely recognized that transmission electron microscopy is one of the central techniques used for characterization of nano-materials. Recent advances and improvements in the field of high resolution electron microscopy and microanalysis tools allowed the achievement of remarkable progress in research and development of materials on the nanometer scale. Today most nano-laboratories are equipped with modern electron microscopes that allow one to combine HRTEM, STEM, HAADF-STEM, EELS and EDS within a single instrument. Ultimate performance of such systems strongly depends on the properties and characteristics of the electron source. The latest generations of the microscopes are usually based on a field emission gun which, in comparison with thermionic electron sources, is characterized by substantially higher electron current density, better coherency, smaller energy spread and, therefore, has an obvious advantage in forming a fine and bright electron probe. This allows one to obtain not only high quality high resolution images, but also affords better analytical sensitivity for EDS and EELS analysis that manifests itself in providing rich local chemical information with better spatial resolution. In the absence of a field emission gun, a high resolution transmission electron microscope with a conventional LaB₆ gun can also be very effective in performing most of the routine works aimed at the characterization of nano-materials structure.

In this paper we report on our experience in use of JEOL JEM-2100 (LaB₆) electron microscope with HT pole-pieces that was installed at the Bar-Ilan Institute of Nanotechnology and Advanced Materials (BINA) in 2008. The instrument equipped with Noran System Six EDS system for elemental analysis and integrated with a scanning device comprising ADF and BF detectors, became a multi-disciplinary "workhorse" providing services for investigations in the nanofield encompassing a wide variety of topics. Below we demonstrate the excellent performance of the microscope and present some results showing its contribution to our studies of nano-materials.

The Microscope room and the operating environment
The installation of the microscope was completed in August 2008. It was installed on the ground floor without any special separation from the building foundation, in a room which barely meets the minimal accommodation requirements. The AC fields at the site were within the acceptable norm (less than 1 m Gauss), the HT tank and power supply block were placed at the distance of about 1.5 m from the microscope column. Water chiller and UPS unit generating noise and heat were set outside the room. The main problem that we faced was that of cooling the room without causing significant air flow that would disturb the microscope performance. We installed a standard air-conditioning unit set at about 21°C with the outlets arranged to blow the cooled air away from the microscope column. As follows from the Fourier transform (see inset) taken from the area outlined by the square, the lattice fringes with spacing as fine as 1.17 Å could be observed. Such lattice resolution achieved with our instrument appears to be even better than that specified in the official table of the key-features published for JEM-2100 (LaB₆) microscope (lattice resolution 0.14 nm).

The ability of the instrument to detect image features with faint contrast is demonstrated in Figure 1b where the 2-3 nm thick amorphous Al₂O₃ coating of an individual TiO₂ nano-particle is clearly seen. Another example is related to the performance of the instrument in STEM mode which we usually employ with EDS elemental mapping or line scan to provide information on the chemical composition of very small volumes of material. Figure 2 shows the STEM image of the cross-section of the amorphous SiO₂ layer deposited on the crystalline Si <100>, prepared by FIB technique [1]. Ge⁺ ions were implanted into the SiO₂ layer and the subsequent annealing process gave rise to the growth of nano-crystalline particles of Ge. The image clearly shows well separated nano-particles of Ge and the line scan profile for the elements Ge (yellow), Si (green) and O (red). According to the size of the smallest particles, we can estimate that the resolution capability of the instrument afforded by STEM is about 10 nm.

Applications in nano-materials research
The Bar-Ilan Institute of Nanotechnology & Advanced Materials (BINA) is engaged in advanced scientific research and technological applications in the field of nano-science and technology. The institute includes six research centers: Nano-Materials, Nano-Medicine, Nano-Energy, Nano-Photonics, Nano-Magnetism and...
Nanotechnology was involved in creating unusual properties in textile material, such as antibacterial properties. For this purpose nanoparticles of Al₂O₃ were deposited on fabrics by sonochemical irradiation technology [3]. From the coated cotton material, specimens for microscopic examination were prepared using the epoxy embedding technique and ultra microtome cutting.

A JEM-2100 (LaB₆) electron microscope was used to analyze the particles’ morphology and size. Two particular features characterize this study: (a) the low-dose imaging technique was applied because of instability of the epoxy cross sections under the electron beam, (b) it was impossible to identify the Al₂O₃ nano-particles by conventional electron diffraction technique, since the diffraction reflections were very weak. Therefore high resolution images of nano-particles showing lattice fringes and Fourier transform of these images were used in the analysis of the particles' structure.

The fiber coated with Al₂O₃ is shown in the TEM micrograph in Figure 3. A few individual Al₂O₃ crystalline nano-particles are clearly visualized in the Bright field, and in the Dark field (see inset) images.

The STEM capabilities of the microscope...
allowed the application of an elemental mapping technique for analysis of the distribution of $\text{A}l_2\text{O}_3$ nano-particles over a coated material. Figure 4 demonstrates the results of Al-mapping which, in fact, shows the Al-containing particles covering the fiber (Al-blue).

The identification of the nano-particles was based on the analysis of their high resolution images. An example is given in Figure 5 showing a high resolution image taken from the particle marked by the arrow in Figure 3. Inset (a) represents the magnified portion of the image outlined by the white square. The distances measured between lattice fringes were $0.28 \text{ nm}$, $0.25 \text{ nm}$ and $0.25 \text{ nm}$ matching, respectively, the interplanar spacings $d_{220}$, $d_{131}$, and $d_{311}$ in the orthorhombic $\delta$-$\text{Al}_2\text{O}_3$ structure (the dimensions of the unit cell are $a = 7.934 \text{ Å}$, $b = 7.956 \text{ Å}$, $c = 11.75 \text{ Å}$, [4]). Inset (b) is the computed Fourier transform of the image in inset (a) which, like a diffraction pattern, was indexed on the basis of the unit cell of $\delta$-$\text{Al}_2\text{O}_3$ structure.

**Investigation of materials for advanced lithium-ion batteries [5,6]**

The JEM-2100 (LaB$_6$) microscope was used in the study of a variety of electrode materials for rechargeable Li-ion batteries. The materials based on the LiMPO$_4$ compounds ($M=\text{Fe, Mn, Co, or Ni}$) [7] are considered as particularly promising, and among them mixed-transition-metal olivine compounds, such as Li(Mn,Fe)PO$_4$, exhibit excellent performance. Intensive investigations of these materials were carried out at Bar-Ilan University by the electrochemistry group, one of the leading groups in the field. We present herein some results of the electron microscopic study of the structure of a carbon coated LiMnP$_{0.8}$Fe$_{0.2}$PO$_4$ compound which was synthesized by a solid-state reaction [5]. Presumably, the carbon coating enables the active mass to have excellent electronic conductivity and also serves as a barrier against detrimental surface reactions between the active mass and solution species.

The high resolution electron micrograph in Figure 6 shows a typical carbon-coated nanoparticle of the LiMnP$_{0.8}$Fe$_{0.2}$PO$_4$ compound. The core-shell structure of the nano-particle is clearly seen: the core is the crystalline LiMnP$_{0.8}$Fe$_{0.2}$PO$_4$ compound and the thin shell is a coating layer of graphitic carbon (~5 nm thick). It is worth noting that the contrast of the image enables good visualization of the carbon layer coating the LiMnP$_{0.8}$Fe$_{0.2}$PO$_4$ nano-particle, despite the background due to the presence of carbon substrate.

The EDS spectrum (Figure 7) taken from a ~25 nm area shows that Mn, Fe, P, O, and C are all present in the sample. An atomic ratio of 3.6:1 calculated for Mn and Fe is in good agreement with the expected ratio of 4:1 found in high resolution SEM.

The structure of the nano-particle was identified using the computed Fourier transform of the portion of the image within marked area (white square in Figure 6). The "reflection spots" on the Fourier transform (inset in Figure 6) were successfully indexed in terms of the orthorhombic unit cell [6] ($a = 10.414 \text{ Å}$, $b = 6.081 \text{ Å}$, $c = 4.73 \text{ Å}$) that represents the structure of both LiFePO$_4$ and LiMnP$_4$ compounds. Because these compounds are structurally similar they could not be distinguished in the high resolution image of the core of the particle. It was therefore suggested that the material should be considered as a solid solution of LiMnP$_4$ and LiFePO$_4$ compounds which are integrated and interconnected with one another at the atomic level.

**The study of the structure of nano-composite solar cells [8,9]**

Development of nano-composite solar cells as an alternative to existing silicon photovoltaic devices has become a very attractive subj-
ject. In the nano-composite solar cell, quantum dots can act as photo-absorbers which inject charge carriers from their excited state into adjacent electron and hole conducting media.

In the present work, quantum dots of CdS were deposited by chemical bath deposition onto the surface of mesoporous film (core material) consisting of interconnected TiO$_2$ nano-crystals. In order to improve the performance of the solar cells, an additional thin layer of amorphous TiO$_2$ was deposited onto the quantum dots-sensitized core.

There was a significant challenge to characterize the morphology, chemistry and crystallographic structure of all constituents of the obtained nano-composite material because the extremely small size of the CdS and TiO$_2$ nano-particles, about 5-10 and 20-40 nm respectively. Moreover, it was important to identify the amorphous TiO$_2$ layer which was approximately 2 nm thick. These tasks were successfully fulfilled using our JEM-2100 LaB$_6$ electron microscope.

![Fig.6](image1.png)  High resolution micrograph of a carbon coated nano-particle of LiMn$_{0.8}$Fe$_{0.2}$PO$_4$. A 5 nm thick carbon coating is clearly seen. The inset is the computed Fourier Transform taken from the marked area, showing sets of reflections corresponding to the interplanar spacing, $d_{210}$, $d_{201}$ and $d_{011}$ in the orthorhombic structure of LiMn$_{0.8}$Fe$_{0.2}$PO$_4$.

![Fig.7](image2.png)  EDS spectrum recorded from nanoparticles of LiMn$_{0.8}$Fe$_{0.2}$PO$_4$, showing characteristic peaks of elements C, O, P, Mn and Fe. The Cu peak is from the specimen grid.
**Summary**

The capabilities of high resolution transmission electron microscope JEOL JEM-2100 with a conventional LaB₆ gun allow the effective employment of the instrument in most of routine structure studies of nano-materials. Nano-particles as small as 5-10 nm can be unambiguously identified by Fourier analysis of high-resolution images combined with elemental X-ray microanalysis. This is demonstrated through several examples of investigations in the field of nano-technology that were carried out at Bar-Ilan Institute of Nanotechnology and Advanced Materials. Indexing of the Fourier transform patterns was successfully used for identifying the AlₓOᵧ nano-particles of antibacterial coatings, the LiMn₀.₈Fe₀.₂PO₄ nano-particles in materials for rechargeable batteries, the TiO₂ nano-particles with CdS quantum dots in nano-composite solar cells and Fe₃O₄ nano-particles entrapped within nano-porous microspheres fabricated from cross-linked poly-divinyl benzene (PDVB) [10]. The microspheres were then annealed in air at 250 °C, and in argon atmosphere at 500 °C and 800 °C. **Figure 9** shows the STEM bright field images with the iron mapping (iron in red) of the microspheres annealed at 250, 500 and 800 °C. It can be seen that increasing the annealing temperature results in a decrease in the size of the microspheres.

The structure of the iron containing particles was investigated in TEM mode using either conventional selected area diffraction (SAD) technique or Fourier analysis of high resolution images, depending on the size of the particles. Inset (a) in **Figure 10** is an electron micrograph of a typical microsphere with entrapped particles that was prepared at annealing temperature 500 °C; the enlarged area outlined by the white square is shown in inset (b). The EDS elemental analysis of this area with a probe of 25 nm has shown the presence of iron, oxygen and carbon. The high resolution image and the corresponding Fourier transform taken from the particle marked by the arrow in inset (b) are shown in insets (c) and (d), respectively. The Fourier pattern was indexed in terms of the unit cell of Fe₃O₄ (cubic FCC a = 8.35 Å).

**Acknowledgement**

The author wishes to thank Prof. M. and iron oxide particles entrapped within nano-porous microspheres. [10]

In this study transmission electron microscopy was used for analyzing the morphology, elemental content and structure of the magnetic micro-particles entrapped within nano-porous microspheres. Nano-porous materials are widely used as adsorbents, catalyst supports and biocompatible materials. Incorporating magnetic components within the porous material can give rise to many new applications, such as cell separation, enzyme immobilization, diagnostics, molecular biology, MRI contrast agents, drug targeting etc.

**Analysis of magnetic iron and iron oxide particles entrapped within nano-porous microspheres.** [10]

**Figure 8** represents a high resolution electron micrograph taken from mesoporous TiO₂ film sensitized with the quantum dots of CdS. In this micrograph TiO₂ and CdS crystalline nano-particles display typical lattice-fringe contrast, and the amorphous TiO₂ shell is also distinguishable, exhibiting a faint contrast, slightly brighter than the rest of background. The Energy dispersive X-ray spectrum obtained with the relatively large electron probe (30 nm in diameter) shows the presence of Ti, Cd, S and O elements in the film. However, the brightness of the LaB₆ electron source was not high enough to allow using sub-nanometer probe size in order to identify individual nano-particles of TiO₂ and CdS nano-particles. This is illustrated in the two insets, (a) and (b), showing Fourier transform patterns taken from the areas numbered, correspondingly, 1 and 2 in the image. The pattern in the inset (a) was indexed on the basis of a tetragonal unit cell of anatase TiO₂ (a = 3.78 Å, c = 9.5 Å), while the pattern in the inset (b) was unambiguously indexed in terms of a hexagonal structure describing CdS (cell parameters: a = 4.15 Å, c = 6.73 Å). This was sufficient proof of the presence of CdS and TiO₂ nano-particles in the sample.
Talianker for his valuable assistance in writing this article. The author acknowledges Mr. S. Levy, Dr. I. Perlishtein, Dr. S. K. Martha, Dr. B. M. Markovsky, M. M. Shalom and Dr. D. Amara for their cooperation and contributions to this paper. They appear as authors in each referenced paper. Special thanks to Prof. D. Aurbach for his encouragement and support and to Dr. M. Ben-Tzion who offered valuable editorial comments.

References


Fig. 9 Scanning transmission electron micrographs displaying the Fe-Kα distribution map within the microspheres fabricated from PDVB with entrapped nano-particles of iron oxide (red). The images correspond to annealing temperatures 250, 500 and 800 °C. Increasing the annealing temperature results in a decrease in the size of the microspheres.

Fig. 10 Electron micrograph representing an individual PDVB microsphere with nano-pores containing iron (annealing temperature is 500 °C). Insets show: (a) the general view of the microsphere; (b) the enlarged area outlined by white square in the inset (a); (c) the high resolution image of the particle marked by arrow; (d) Fourier transform taken from the high resolution image. The indexing of the Fourier pattern shows that particle is Fe₃O₄.
Development of JMS-S3000: MALDI-TOF/TOF Utilizing a Spiral Ion Trajectory

We have developed the JMS-S3000, matrix assisted laser/desorption ionization time-of-flight mass spectrometer (MALDI-TOFMS). An innovative ion optical system, which achieved a spiral ion trajectory, surpassed basic specification of the reflectron ion optical system presently used in most commercially available TOFMSs. Furthermore, we have developed the TOF-TOF option for the JMS-S3000. In the case of attaching the TOF-TOF option, a spiral ion optical system is adopted for the first TOFMS, whereas a reflectron ion optical system with offset parabolic reflector is adopted for the second one. Utilizing the spiral trajectory ion optical system, the JMS-S3000 provides unprecedentedly high mass resolution and high precursor ion selectivity. In this paper, we demonstrate not only the high mass resolution of more than 60,000 (FWHM) at m/z 2093 but also achievement of high mass resolution over a wide mass range. In addition, we present the high selectivity that enables selection of monoisotopic ions of precursor ions. By selecting only monoisotopic ions of precursor ions, one signal peak corresponding to each fragmentation channel is observed on a product ion spectrum. Consequently, the analysis of the product ion spectrum is made clearer.

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Introduction

The time-of-flight mass spectrometer (TOFMS) is one of mass spectrometry techniques, which include the quadrupole mass spectrometer, the magnetic sector mass spectrometer, the ion trap mass spectrometer and the Fourier transform ion cyclotron resonance mass spectrometer. In the case of TOFMS, ions of various m/z values, which are generated in the ion source, are accelerated to the detection plane by a pulse voltage applied from a starting time of data acquisition. Since the time-of-flight of ions at the detection plane are proportional to the square root of their m/z values, the ions generated in the ion source can be separated. One of the TOFMS feature is fast measurement, which is due to the unnecesity of scan for any physical parameters such as electric or magnetic fields. Recently, not only a single type mass spectrometer, but also a tandem type mass spectrometer connected with the quadrupole mass spectrometer (Q/TOF) or tandemly connected two TOFMSs (TOF/TOF) are available.

The mass resolution of TOFMS is expressed by $T/2\Delta T$, where $\Delta T$ is the time-of-flight distribution of the ion group with the same m/z value (ion packet) at the detection plane (that is, spatial distribution of the ion packet in the flight direction at the detection plane) and, $T$ is centroid of the time-of-flight distribution. Since TOFMS was invented in 1964 [1], its mass resolution has been improved by increasing $T$ and decreasing $\Delta T$. In 1955, a unique acceleration technique was developed, which focuses the initial space and energy distributions at the detector surface in the flight direction. Applying this technique, the mass resolution was increased by decreasing $\Delta T$ [2]. Furthermore, in the early 1970s, a new technique was developed. In this technique, the focus position defined by the above-mentioned acceleration technique is chosen as the start point, and an ion optical system that is composed of ion mirror [3] or electrostatic sectors [4] is placed at the post stage. This innovation made it possible to increase the time-of-flight T without increasing $\Delta T$, and led to a dramatic improvement of the mass resolution. Recently, most of commercially available TOFMS instruments use ion mirrors, and their flight paths are 1 to 3 m. For further improvement in the mass resolution of TOFMS, another types of ion optical systems have been proposed. They are the multi-reflecting type [5] and the multi-turn type [6-7] ion optical system where ions fly multiple times on the certain trajectory. These two ion optical systems theoretically achieve an infinitely long flight path in a compact space, and improved the mass resolution. However, they have the limitation of the mass range because ions with large speed (ions with small m/z) lap the ions with small speed (ions with large m/z) when the ions flying on the same trajectory multiple times.

We have developed an original ion optical system that utilizes a spiral ion trajectory. This ion optical system can overcome the "lap" problem present in multi-reflecting and multi-turn type ion optical systems. In addition, it is possible to achieve mass resolution and mass accuracy higher than those of widely used reflectron ion optical systems. In this paper, we describe the design of the spiral trajectory
Design of the spiral trajectory ion optical system

Multi-turn type ion optical system technique was applied for development of the spiral trajectory ion optical system. Especially, a combination of the “perfect focusing” and “multi-turn” [12] techniques developed at Osaka University, which achieved highest mass resolution in the world, was considered the most suitable for development of the spiral trajectory ion optical system. For conversion of a multi-turn type ion optical system for a spiral trajectory ion optical system, it is necessary to move ion trajectory perpendicular to the orbit plane. In order to achieve this, we have designed the system so that the ion trajectory becomes slightly tilted to the orbit plane. The advantage of the design is that there is no need for the mechanism to transfer the ions to the next layer. There are concerns about degradation of mass resolution due to the trajectory deviation from a multi-turn type ion optical system. However, the effect should be negligible by keeping the injection angle to several degrees.

Practically, we have designed the spiral trajectory ion optical system based on MULTUM II [7] construction, which consists of four toroidal electrostatic sectors (cylindrical electrodes with two Matsuda plates). The schematic of the ion optical system is shown in Fig. 1. To achieve a spiral trajectory, we have constructed a layered toroidal electric field (TES) by placing (number of cycles +1) Matsuda plates into the cylindrical electrostatic sectors. The Matsuda plates are arranged within certain equal distances, in the space between internal and surrounding electrodes. The three types of voltages applied on TES 1 to 4 is that of the internal electrode, external electrodes and Matsuda plates. Corresponding voltages are supplied to every Matsuda plates, internal and external electrodes of TESs 1 to 4.

Also, four TESs were placed so that they correspond to MULTUM II when looked from the orbit plane. Y direction was set perpendicular to the periodic orbit plane. In development of the MALDI-TOF/TOF, we have made Y direction to horizontal. The TES 1 in the Fig. 1 shows the external electrode is removed so that it can be seen the Matsuda plates are equally spaced. Ions fly through the center of the space, formed by Lx and Ly. Ion passes the same layer of TESs 1 to 4, and after passing the TES 4, it enters to the next layer of TES 1. The process is repeated for several cycles; the ion thus draws a spiral trajectory and reaches the detector (DET1) (Green line in the Figure 1 represents the ion trajectory). The injection angle θ into the layered toroidal electric field can be expressed as follows,

\[ \tan \theta = (L_y + L_m) / L_c \]  

where, \( L_m \) is the thickness of a Matsuda plate and \( L_c \) is the one cycle length.

As mentioned above, owing to the usage of four TESs of the same structure in its construction, the ion optical system can achieve a complicated trajectory within a simple structure.

Production of MALDI-TOF/TOF utilizing spiral trajectory ion optical system

We have developed MALDI-TOF/TOF utilizing the spiral trajectory ion optical system. It consisted of the first TOFMS using the spiral trajectory ion optical system and the second TOFMS using the reflectron ion optical system. The mass spectrum measurement in the first TOFMS is referred as spiral mode, and the product ion spectrum measurement in the second TOFMS as TOF/TOF mode.

A schematic of the system is shown in Fig. 2 (ion source and the detector DET1 of the first TOFMSs are omitted). Spiral trajectory is set to eight cycles of 2.093 m per each. A distance between central trajectories of the adjacent layers is 58 mm, an injection angle is 1.6 degree according to equation (1). Y direction is set as horizontal, so the injection angle is achieved by tilting the extraction direction of the ion source 1.6 degrees from a horizontal plane.

In the spiral mode, ions fly a spiral trajectory and are detected with the spiral mode detector (though not specified in Fig. 2, it is located similarly to DET1 in Fig. 1). Ion gate is placed in the 7th cycle. It allows eliminating high-intensity matrix ions, which are outside of the data acquisition m/z range.

In TOF/TOF mode, selection width of the ion gate is made narrower and monoisotopic ions of precursor ions are selected out of all isotopic ions of them. It is possible to mechanically move the spiral mode detector out of the trajectory so that precursor ions can be introduced into the collision cell. Ions, that entered a collision cell, collide with rare gas inside of the cell with a kinetic energy of approximately
20 keV, and generate fragment ions. Precursor ions and fragment ions are mass-separated in a reflectron ion optical system that combines an offset parabolic reflector (OPR) [13] and a reacceleration mechanism. OPR is a reflectron connecting a linear and parabolic electric fields. It allows simultaneous observation of ions, from low m/z fragment ions up to precursor ions. In addition, in order to increase transmission of ions, fine adjustment of the ion trajectory is enabled by installing two deflectors (DEF1 and DEF2) on both sides of the collision cell.

Evaluation of MALDI-TOF/TOF with spiral trajectory ion optical system utilized

Figure 3 shows mass spectrum of six types of peptide mixtures (in order of m/z increase: Bradykinin fragment 1-7, Angiotensin II, Angiotensin I, P14R, ACTH fragment 1-17, ACTH fragment 18-39). The mass spectrum of Angiotensin II and ACTH fragment 1-17 are also displayed as an enlarged image. Mass resolution is 58000 (FWHM) and 73000 (FWHM) respectively. The mass error of ACTH fragment 1-17 is 0.16 ppm, when internal calibration is performed among five peptides except ACTH fragment 1-17. It became clear from the above mentioned facts that distance of flight for spiral trajectory ion optical system is 17 m, which is 5 times longer than that of the conventional reflectron type ion optical systems. This allows enhancement of mass resolution and mass accuracy. Figure 4 shows the relation between m/z value and mass resolution when mass resolution is adjusted with ACTH fragment 1-17. Figure 4 shows that it is possible to achieve high mass resolution simultaneously in a wide m/z range. This overcomes the problem of MALDI-TOFMS utilizing conventional reflectron type ion optical system that could achieve high mass resolution only in a narrow m/z range.

Figure 5a shows a product ion spectrum diagram of Poly (oxypropylene), acquired in TOF/TOF mode. Selected precursor ions are monoisotopic ions from [M + Na]+ series with m/z 1027. A numbers of fragmentation channels from sodium ions as fragment ion to precursor ion are observed. The enlarged spectrum around m/z 780 is shown in Fig. 5b. The system is able to select only monoisotopic ions of precursor ions, therefore each fragment channels can be observed as one peak without any isotopic peaks. Two peaks in Fig. 5b indicate different fragmentation channels. It indicates that 2u different fragmentation channels can be clearly separated. Figure 5c displays an image of the same m/z range as in Fig. 5b when measured with conventional TOF/TOF. Pecursor ion selectivity of traditional TOF/TOF is insufficient so that the fragment ions from all isotopic ions of precursor ions are analyzed in the second TOFMS. Thus every fragmentation channels of product ion spectrum include isotopic peaks. As a result, when m/z values of monoisotopic ions of two fragment channels are close, such as 2 u, their isotopic peaks are overlapped and are impossible to be clearly identified. The high precursor ion selectivity originated from the spiral trajectory ion optical system used in this system makes the structural analysis of chemical compounds much easier.

Conclusion

This paper reports on the development of the spiral trajectory ion optical system. Also, the paper describes the development of MALDI-TOF/TOF, which combines a spiral trajectory ion optical system and reflectron type ion optical system utilizing offset parabolic ion mirrors. Innovative ion optical system introduced to the JMS-S3000 has overcome preexisting problems related to conventional MALDI-TOF and MALDI-TOF/TOF. Thus, the JMS-S3000 is expected to play a significant role in various areas.

References

Fig. 4 Relation between m/z value and mass resolution.

Fig. 5 Product ion spectrum of Poly(oxypropylene).

Rapid Characterization of Bacteria Using ClairScope™ and SpiralTOF™

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In many fields such as clinical diagnosis and food inspection, there is a demand for rapid, reliable and simple-to-use methods for characterizing bacteria. This paper explores the use of two new and innovative instruments called ClairScope™ and SpiralTOF™ for this rapid characterization. The JEOL JASM-6200 ClairScope™ integrates an optical microscope (OM) with a scanning electron microscope (SEM) where it is possible to observe samples in solution, in an open system, by the SEM at atmospheric pressure. This type of sample would typically require extensive sample pretreatment that would take a day or more with conventional SEM techniques. With the recently developed ClairScope™, fine morphological observation can be performed directly in solution with simple sample pretreatment of one hour or less. The JMS-S3000 SpiralTOF™, a matrix-assisted laser desorption/ionization mass spectrometer (MALDI-MS) with a spiral ion trajectory, can characterize ribosomal proteins and phospholipids with high accuracy. Ribosomal proteins are biomarkers for phylogenetic classification, and phospholipids are used for chemotaxonomic analysis. The combination of ClairScope™ and SpiralTOF™ are found to be powerful instruments for the characterization of bacteria.

Introduction

Rapid characterization methods are in demand for bacteria, which are simple to use and reliable, in a variety of fields such as clinical diagnosis, food inspection, and environmental energy industries. Bacterial characterization methods can be divided into two categories: analysis of phenotype and genotype. Phenotype analysis includes a morphological study and chemotaxonomy where analysis of bacterial cell components such as proteins and lipids are analyzed. Genotype analysis includes gel electrophoresis and DNA sequencing using a sequencer.

In many cases, a skilled operator can identify the species of bacteria using an optical microscope combined with supplemental information. However, optical microscope (OM) has limited resolution and with bacterial size typically smaller than a few micrometers, detailed structural information cannot be obtained. The use of scanning electron microscope (SEM) overcomes this resolution limitation but often requires long sample pretreatment such as dehydration and fixation that can take a day or even longer.

A chemotaxonomy, based on biochemical analysis, is effective in investigating characteristics of bacterial strains. Yet with current methodology, sample preparations are cumbersome. Also, these methods tend to be affected by differences in culture conditions, sample preparation techniques and measurement conditions which can lead to results that are not as reproducible as desired. The reduction in cost, improved throughput and larger databases are making DNA analysis methods more popular. However, in principle, errors in amplification and sequencing cannot be avoided. Therefore, using polyphasic methods to characterize bacteria is of prime importance.

In this paper, possibilities of new rapid characterization methods for bacteria were studied based on both phenotype and genotype. Escherichia coli NBRC 3301 was used as a model strain. The JASM-6200 ClairScope™ (atmospheric scanning electron microscope: ASEM) [1], was used to observe the morphology of the bacteria at atmospheric pressure. The JMS-S3000 SpiralTOF™, a matrix-assisted laser desorption/ionization mass spectrometer (MALDI-MS) [2] with a spiral ion trajectory, was used to analyze the ribosomal proteins and phospholipids.

Morphological Observation of Bacteria with the JASM-6200 ClairScope™

The configuration of the JASM-6200 ClairScope™ is shown in Fig. 1. This microscope consists of an inverted SEM that incorporates a thin-film (silicon nitride, SiN)-windowed ASEM specimen dish on top. The film with a thickness of 100 nm allows transmission of the electron beam and also maintains a vacuum in the ASEM. These features enable SEM observation according to the following procedure: an ASEM specimen dish with the sample is placed on the ClairScope™, the sample is scanned with the electron beam from underneath through the thin SiN film, and then backscattered electrons emitted from the sample are detected. The ClairScope™ also includes a wide field OM just above the ASEM specimen dish for observation of the same field of view. This innovative microscope enables observation of samples such as bacteria, in solution at atmospheric pressure, using both optical and SEM imaging. Rapid and simple SEM observation can be achieved without the long dehydration and fixation sample treatments typically required with conventional SEMs.

In this study, the E. coli NBRC 3301 was grown in Luria-Bertani medium at 30°C for 8 h. The E. coli NBRC 3301 was harvested by centrifugation then washed twice with phosphate-buffered saline (PBS). They were re-suspended in the PBS and put on the ASEM specimen dish that was coated with poly-L-lysine. At this point, the sample was fixed with 2% paraformaldehyde/1% glutaraldehyde in PBS for 10 min. After washing, the sample was stained with 0.6% platinum blue [3] for 3 h. ASEM images of E. coli NBRC 3301 are shown in Fig. 2. Even with such a short sample pretreatment time, the ClairScope™ provided high resolution images where rod-shaped E. coli NBRC 3301 smaller than 2 μm were clearly visualized.

Although information obtained through imaging with the ClairScope™ can look different from that obtained by conventional SEM or transmission electron microscope, this new SEM not only allows for rapid observation but also enables much simpler and faster sample pretreatment prior to imaging for high throughput analyses. Also, with the recent advancement in fluorescent labeling, complimentary information can be obtained through the OM and correlating the information from both the OM and ASEM can play an important role in the characterization of bacteria.

Analysis of Ribosomal Proteins and Phospholipids with the JMS-S3000 SpiralTOF™

The JMS-S3000 SpiralTOF™ is shown in Fig. 3 with its ion optical system. This instrument is an advanced MALDI TOFMS, for the analysis of a wide range of samples such as lipids, synthetic polymers, peptides, and pro...
teins, through the combination of the spiral mode and the linear mode of operation. In particular, the spiral mode has an ion flight length of 17 m which is achieved by the ion optical system having a spiral trajectory. This suppresses beam broadening to prevent degradation of mass resolution and mass accuracy. Therefore, the SpiralTOFTM provides higher mass resolving power and higher mass accuracy than conventional MALDI TOFMS. This paper reports on the analysis of ribosomal proteins in the linear mode and the analysis of phospholipids in the spiral mode.

Analysis of ribosomal proteins with the SpiralTOFTM in linear mode

In recent years, mass spectral patterns obtained by MALDI-MS have been used for rapid identification and classification of bacteria. In this method, ribosomal proteins are observed and their spectra are compared with reference spectra from bacterial strains stored in a library database. This provides identification of bacteria at "species level" which can be obtained by 16S rRNA gene sequencing [4].

On the other hand, the characteristics of bacteria such as antibacterial activity and toxicity are frequently different at the "strain level". To discriminate bacteria at the strain level, and to classify the bacteria based on genotype, we have used observed masses of ribosomal proteins as biomarkers instead of the mass spectral fingerprints [5-7]. Observed masses of ribosomal proteins in MALDI mass spectra have been precisely assigned with calculated mass from DNA sequence. We have shown that it is possible to discriminate bacteria at
Compositional analysis of phospholipids with the SpiralTOF™ in spiral mode

The cell components of bacteria are much more diverse than those of eukaryote. Thus, analyzing the components such as lipids, peptidoglycans, and proteins is effective for bacterial characterization at the strain level. This is known as chemotaxonomy. Lipids including fatty acids, phospholipids, sphingolipids, mycolic acids and the isoprenoid quinine group are often studied. In particular, glycerophospholipids are included in all bacterial cells so that analyzing them is valuable. The compositional distribution of hydrocarbon chains, especially carbon numbers and degree of double bonds, as well as the chemical structures of hydrophilic groups are important biomarkers for chemotaxonomy of bacteria.

Ishida et al. proposed the on-probe method where whole bacterial cells are deposited directly onto a MALDI target plate, and intact phospholipids from the cells are analyzed by MALDI-M S [9]. This simplified sample pretreatment significantly reduces sample preparation time to several minutes. Since bacteria normally contain several types of phospholipids with different chemical structures, mass spectra peaks for phospholipids frequently show overlaps that are not easily resolved. It is crucial to separate and identify these peaks clearly and precisely for accurate characterization of bacteria. For this purpose, the SpiralTOF™ is especially valuable, since it has high mass resolving power and high mass accuracy (at m/z ~1,000, peak of Δm <0.04 Da can be separated).

The sample preparation for phospholipids from whole bacterial cells were carried out according to the method established by Ishida et al. [9]. Polymerix (Sierra Analytics Corporation) was used for data analysis. Fig. 4 shows a MALDI mass spectrum for E. coli NBRC 3301. In this spectrum, each peak was clearly separated with high intensity, and these observed peaks were assigned as ribosomal proteins by comparing with the calculated masses. In the bacterial characterization using DNA sequencing, in principle, the possibility of an error in amplification and sequencing processes cannot be excluded. In contrast such errors do not occur in our method because neither amplification nor a sequencing process is used. In addition, ribosomal proteins are always observed independent of culture conditions, because they are typical housekeeping proteins. Thus, our method is highly reliable. Moreover, our method can detect a subtle difference in an amino-acid sequence as a clear peak shift in the mass spectra. This capability provides high sensitivity to variations of the amino-acid sequence, which is related to DNA sequences. Therefore, this simple method provides highly reliable and sensitive information for bacterial characterization.

Conclusion

There is no complete single method which can fully cover the characterization of bacteria. With this in mind, there is a demand for the development of simple, rapid and reliable methods. In this paper, Escherichia coli NBRC 3301 was characterized based on phenotype and genotype using the ClairScope™ and the SpiralTOF™. The ClairScope™ pro-

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Fig. 4 MALDI mass spectrum of E. coli NBRC 3301 (linear mode).

Fig. 5 MALDI mass spectrum of phospholipids extracted from whole cells of E. coli NBRC 3301 (spiral mode).

Fig. 6 Composition of PE extracted from whole cells of E. coli NBRC 3301. [40] JEOL News Vol. 45 No.1 40 (2010)
vided morphological observation with simple sample pretreatment methods requiring only one-hour (fixation and staining), versus the treatment methods required with conventional SEM which can take up to ten times longer. The advantage here is rapid morphological observation at high magnifications with very simple and fast sample pretreatment. The ClairScope™ is expected to be especially valuable for slow-growing bacteria including pathogenic ones, since it also requires a small amount of sample.

In addition, the SpiralTOF™ enabled highly reliable analyses of bacteria with pretreatment times that take only a few minutes. The linear mode was used for the analysis of ribosomal proteins. These proteins act as biomarkers for phylogenetic classification of bacteria at the strain level. The spiral mode was used for the analysis of phospholipids, which are biomarkers for chemotaxonomy.

In many cases, the reliability of analyses that use rapid and simple methods is not high. However, the use of these two new and innovative instruments are not only simple to use, but also provides fast and highly reliable results.

The new methods described in this paper are well suited for high throughput characterization of bacterial samples. First, morphological observation with the ClairScope™ can provide insight such as whether a sample contains bacteria or sometimes whether they are pathogenic combined with some other information. Second, using the SpiralTOF™ in linear mode, ribosomal proteins which are used as biomarkers to distinguish and classify the bacterial samples at the strain level, can be analyzed. This also determines appropriate pre-treatment for chemotaxonomy of relevant strains. Third, components of bacterial cells such as phospholipids and mycolic acids, can be analyzed using the SpiralTOF™ in spiral mode. The combination of these methods will give a broad range of information (Fig. 7) and can provide complementary information for other methods such as sequence analysis of 16S rRNA gene.

References

Fig. 7 Conceptual image of rapid characterization of bacteria using both ClairScope™ and SpiralTOF™.
Micro Area Analysis with JXA-8530F (FE-EPMA)

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The FE-EPMA, an electron probe micro analyzer (EPMA) equipped with a Schottky field emission (FE) electron gun, is designed to enhance the micro area analysis capability, achieving an analytical area of only 0.1 μm in size. Micro area analyses were studied on stainless steel and solder samples with a FE-EPMA to evaluate its spatial resolution, micro particle detection, and ability to quantify micro areas.

Introduction

FE-EPMA, an electron probe micro analyzer (EPMA) equipped with a Schottky field emission (FE) electron gun, is designed to enhance the micro area analysis capability [1], achieving an analytical area of the order of 0.1 μm across in size.

Typically, the analytical area of EPMA has been about 1 μm in both width and depth. The size of an analytical area is determined by the size of the electron probe at the surface and the spread of scattered electrons within the sample. At an accelerating voltage in the range of 15 to 20 kV, the range used most frequently in EPMA, the analytical area is principally determined by the area of electron scattering within the sample, which is typically around 1 μm in diameter.

At lower accelerating voltages, the analytical area is reduced because the electron scattering within the sample becomes smaller. However, it is also critical not to decrease the accelerating voltage during high spatial resolution analyses because the size of the electron probe becomes larger at lower accelerating voltages. In EPMA with a tungsten filament, the horizontal spatial resolution does not improve significantly when the accelerating voltage is lowered to 15 kV or less. The use of a LaB₆ gun, with its ability to achieve a finer probe size, is effective for improving the horizontal spatial resolution, but only at accelerating voltages down to 10 kV [2].

The EPMA can analyze almost all elements at accelerating voltages down to 6 kV, when the characteristic X-ray excitation voltage of all the X-ray lines are considered. Therefore, an EPMA with an FE gun, capable of achieving the finer probe at lower accelerating voltages and high probe currents needed for analysis, can improve the micro area analysis capability over the traditional EPMA with a tungsten or LaB₆ gun.

We have studied micro area analyses of stainless steel and solder samples with FE-EPMA to evaluate its performance in terms of spatial resolution, micro particle detection, and quantification of micro areas.

FE-EPMA (JXA-8530F)

JXA-8530F (Fig. 1) is equipped with a high brightness Schottky field emission (FE) gun allowing an electron probe to focus on smaller areas than the conventional EPMA. The FE gun achieves a probe size 1/2 to 1/8 smaller when compared to the tungsten or LaB₆ gun. Alternatively, the FE gun can produce a probe current 20 to 100 times higher than the tungsten or LaB₆ gun with the same probe size (Fig. 2).

An EPMA is commonly used with a probe current of 10 nA to 100 nA. We therefore compared the images of gold particles acquired with FE, LaB₆, and tungsten guns at an accelerating voltage of 10 kV and a probe current of 100 nA (Fig. 3). The results show...
that the FE gun, under conditions frequently used in actual analysis, is definitely superior to the LaB$_6$ or tungsten gun in terms of spatial resolution.

In addition to the electron gun, the JXA-8530F integrates various features that support high magnification analysis. It uses a two-stage differential pumping system to maintain the vacuum in the electron optics at an optimum level. This prevents changes in the vacuum in the specimen chamber from affecting the gun chamber, thereby achieving probe current stability needed for EPMA analysis. An optional liquid nitrogen trap, sustainable for 10 hours or longer, minimizes the reabsorption of residual gases in the specimen chamber or gases emitted from the sample, allowing samples that are susceptible to gas absorption to be analyzed overnight. Analyzing crystals for low energy X-ray analysis, such as the LDE series and TAPH, are also effective for enhancing the performance at low accelerating voltages.

**Spatial resolution of X-ray mapping**

To obtain X-ray maps with the highest spatial resolution, the probe size must be the smallest, and the accelerating voltage the lowest. If the accelerating voltage is higher, the area from which X-rays are generated becomes larger due to the electron scattering within the sample, thereby reducing the spatial resolution.

The W type EPMA needs to use a higher accelerating voltage (15 to 20 kV) to obtain the probe current needed for typical analysis, because it cannot achieve a small enough probe size at a lower accelerating voltage. The FE gun, however, can produce a probe size small enough for analysis at 10 kV or lower, achieving much higher spatial resolution.

A lead-free solder sample was analyzed at the same accelerating voltage (8 kV) with three different electron guns (Fig. 4). This
lead-free solder contains numerous particles, that 1 μm or smaller in size, of either an Ag alloy or a Cu alloy distributed in the Sn matrix. The FE gun, with the smaller probe size, acquired the best X-ray maps with superior spatial resolution.

The spatial resolution of X-ray mapping of a bulk sample is considered to be around 0.1 μm when the FE gun is used at an accelerating voltage optimized for the probe size and the electron scattering within the sample. The appropriate accelerating voltage for the FE gun varies with different samples, but it ranging from 3 to 6 kV. The accelerating voltage should be lower for samples with a smaller mean atomic number, such as oxides. However, for samples with mean atomic number higher than Fe, the accelerating voltage should be set to 5 kV or 6 kV for optimum results.

Thus, the JXA-8530F, with its FE gun, can achieved a spatial resolution of around 0.1 μm by using a low accelerating voltage.

**Detecting trace elements and micro particles**

The results in the preceding section demonstrate that the JXA-8530F has a spatial resolution significantly better than the conventional EPMA. However, for elemental analyses, other systems are also widely used; those with similar capabilities to the EPMA (JXA-8230/8530F) include the FE-SEM+EDS (JSM-7001F), and those with higher spatial resolution include the AES (JAMP-9500F) and the TEM. The major difference between the EPMA and these other systems is that the EPMA uses wavelength dispersive X-ray spectrometer (WDS) for the elemental analysis. We will focus on two features below that sets WDS apart from the other techniques:

1) Superior detection of trace elements
2) Accurate quantitative analysis

Item (1) is related to the ability to detect micro particles, which is one of the critical factors in high-resolution analysis. Item (2) will be discussed in the next section.

**Figure 5** is a backscattered electron image of a stainless steel sample that contains Nb and C. Bright particles and extremely small particles with the size of 0.1 μm or less, are observed in the matrix. Nb and C maps of the stainless steel sample were collected by both WDS and EDS. **Figure 6** shows the results.

The remarkable difference between the WDS and EDS data can be seen in the distribution of particles in the carbon X-ray image. The WDS carbon X-ray image shows numerous small particles, whereas the EDS X-ray image hardly shows any of these particles. This demonstrates the difference in trace element detection between the WDS and the EDS capability.

**Figure 7** illustrates how particles that are smaller than the analytical area of the EPMA are detected. Electron beam will scatter once they enter the sample. When the probe is placed onto a particle smaller than the analytical area, the beam will spread beyond the particle boundary. Since the particle size is smaller than the volume of the area being measured, the intensity of the measured X-rays will be lower.

**Figure 8** Detection limits under mapping conditions used in Figure 6.

<table>
<thead>
<tr>
<th>Element</th>
<th>WDS</th>
<th>EDS</th>
</tr>
</thead>
<tbody>
<tr>
<td>C</td>
<td>0.5%</td>
<td>2.7%</td>
</tr>
<tr>
<td>Nb</td>
<td>0.3%</td>
<td>1.0%</td>
</tr>
</tbody>
</table>

This demonstrates the difference in trace element detection between the WDS and the EDS capability.
This low X-ray intensity determines whether the trace elements are detectable. Therefore a system effective for analyzing trace elements is also best for analyzing micro particles. This applies to thin film analysis as well.

The detection limit of WDS or EDS is defined as follows:[3]

\[ C_{DL} = \frac{3.29a}{\sqrt{n t P P/B}} \]

\( C_{DL} \): Detection limit (mass %)
\( a \): Correction coefficient (ZAF etc.)
\( n \): Number of analytical spots
\( t \): Measurement time (s)
\( P \): Peak intensity of standard sample
\( P/B \): P/B ratio of standard sample

The table (Fig.8) shows the results when the parameters for C and Nb are substituted in the formula above. The correction coefficient was assumed to be 1 for this example.

As the table shows, the ability of WDS to detect trace elements in mapping is higher than that for EDS. Thus, WDS is more effective in detecting micro particles than EDS. AES and TEM systems have higher spatial resolution, but the location of particles is critical; particles must be either on the surface (AES) or inside a thin film (TEM). EPMA, on the other hand, can analyze particles containing trace elements that extend from the surface to a 0.1 to 1 μm depth within the sample by changing the accelerating voltage. The EPMA, with its wider range of analytical depths, is often better at detecting micro particles that exist within a sample than AES or TEM. Other examples of EPMA applications include studies of the distribution of Au scattered as micro particles in solder, and the detection of trace components, on the order of ppm, as impurities in stainless steels.

When WDS, effective for trace element detection as well as micro particle analysis, is combined with an FE gun, the result is a powerful analytical tool.

### Spatial resolution in quantitative analysis

One advantage of WDS is its highly accurate quantitative analysis. A solder interface was selected as a test to determine the minimum size area capable of being quantitatively analyzed using WDS.

**Figure 9** is a cross section of a chip resistor mounted to substrate. The interface between the Ni and the solder shown in the cross section was mapped. Results of this area analysis (Fig. 11) show that an Ni-Sn alloy layer occurs next to the Ni, Sn layer of solder is then in contact with the Ni-Sn alloy layer, and a Cu-Sn alloy layer occurs discontinuously between the Ni-Sn alloy and Sn layers. The Cu-Sn alloy layer is Cu6Sn5 which is a result of a Cu coating on the Ni surface that alloyed with the Sn.

Phase analysis was applied to the Cu6Sn5 alloy (Figure 12). The data from the area analysis were quantified and plotted, with the Sn mass concentration in the vertical axis and the Cu mass concentration in the horizontal axis.

When particles 0.2 μm in size are analyzed...
at an accelerating voltage of 6 kV, approximately 10% of the X-rays will be emitted from outside of the particles, assuming a focused beam. Therefore, a circle with a radius of 10% was drawn at a point corresponding to the mass concentration of Cu₆Sn₅ on the scattered diagram, and it was assumed that the area within the circle was where the quantitative analysis was performed.

In the data obtained with the FE gun, numerous points occur within the area of the circle. Data obtained with the LaB₆ gun, shows very few points within the circle corresponding to Cu₆Sn₅, since higher Sn concentrations and lower Cu concentrations were measured due to the larger probe size that interacted with the Sn in the vicinity. Phase analysis was carried out on another region to examine the Cu-Sn alloy distributed in layers at the interface between the solder and Cu (Figs. 13 and 14). The results show that in this sample, the thickness of the Cu₆Sn₅ alloy layer exceeds 1 μm. The data also shows another layer, 0.2 μm thick, at the interface between Cu and Cu₆Sn₅. This layer is a Cu₃Sn₁ alloy.

As before, a circle with a radius of 10% was drawn at each of the points corresponding to the mass concentrations of Cu₆Sn₅ and Cu₃Sn₁ on the scattered diagram. There is little difference between the distribution of Cu₆Sn₅ data taken with the FE gun and the LaB₆ gun. However, for the 0.2 μm thick layer of Cu₃Sn₁ there are numerous points that plot within the circle in the FE gun data, while no apparent correlation was detected within the data from the LaB₆ gun. This demonstrates that the JXA-8530F can quantitatively analyze a layer only 0.2 μm thick. This is an area that is twice the size of the spatial resolution of X-ray imaging, which is 0.1 μm.

The X-ray emitting area spreads from the probe center. It is safe to assume that the area where 50% of the X-rays are emitted determines the spatial resolution. This has been verified by Monte Carlo simulation and actual measurements [2, 4].

For quantitative analysis where a 10% error is permitted, 90% of the X-rays are emitted from the specific area being analyzed. The area where 90% of X-rays are emitted will be approximately twice the size of the area where 50% of X-rays are emitted. A 3 times larger will include most of the X-rays that are emitted and will insure even more accurate quantitative results.

To summarize, the analysis of the solder interface by the JXA-8530F, demonstrates that the spatial resolution of X-ray imaging is about 0.1 μm, whereas for point analysis an area of 0.2 μm is required, if a 10% contribution from the matrix is acceptable, and 0.3 μm is required for high precision quantitative analysis.

**Conclusion**

The JXA-8530F with an FE gun was used for micro area analysis of stainless steel and solder samples to evaluate its spatial performance. The results of the bulk sample analyses at low accelerating voltage shows that the JXA-8530F is capable of:

1) Achieving a spatial resolution of 0.1 μm for X-ray imaging at low accelerating voltages;
2) Detecting micro particles even smaller than the defined spatial resolution using WDS effective for trace element detection;
3) Quantitative analysis of an area only 0.2 μm in size, subject to a 10% interference from the matrix; a higher accuracy is achieved with an area 0.3 μm in size.

**References**


**Fig. 13** X-ray image of the interface between solder and Cu. Cu₆Sn₅ and Cu₆Sn₅ alloys occur between the Sn and Cu. The image shows a Cu₆Sn₅ alloy layer 0.2 μm thick. See attached color images.

**Fig. 14** Phase analysis of Cu-solder interface by FE and LaB₆ guns. The FE gun was able to detect the presence of a Cu₃Sn₁ alloy layer. See attached color images.
Analysis of Insulator Samples with AES

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Introduction

Auger Electron Spectroscopy (AES) makes it possible to analyze a sample at an extremely shallow region such as about 6 nm from the top surface of the sample, enabling you to analyze elements present in a minute area such as 10^2 nm² on the surface if you use the focused electron beam as a probe. However, this attractive feature is limited only to the analysis of conductor and semiconductor samples; on the other hand, for the analysis of insulator samples, it becomes difficult even to obtain the electron image of the sample due to charging phenomenon.

However, it does not necessarily mean that you cannot perform the Auger analysis for the insulator sample. Actually, if you have some knowledge and experience, you can perform the Auger analysis even on the insulator sample while suppressing charging by using the sample tilt method; and you can also perform the Auger analysis by taking the advantage of high spatial resolution of 1 µm diameter or less depending on the state of the insulator sample. In particular, after introducing the "Ar neutralizer gun" that can irradiate low speed Ar ions about 10 to 30 eV to suppress charging, the charge on the sample surface can be controlled relatively easily, making it possible to greatly expand the applicability of the AES analysis to the insulator samples.

This article presents a guiding principle of the way of thinking for the insulator analysis and summarizes the strategy from the basic principle so that the insulator analysis using the AES can be performed without any sophisticated skill.

Basic Principle for Analyzing the Insulator Sample

Kinetic energy of Auger electron and surface potential

Because the kinetic energy (K) of an Auger electron can be uniquely determined by the type of an element and its transition process, the element can be identified from the energy (Fig. 1). The kinetic energy becomes the value reflecting the difference between the binding energies of the electron shells involved in the Auger transition, so in the case of the KL1L2,3 transition process shown in Fig. 1, the kinetic energy can be expressed as in Eq. (1).

\[ K_{KL1L2,3} = (E_K - E_{L1}) - (E_{L2,3} - \phi) \cdots \cdots \cdots (1) \]

where, \( E_K \) is the binding energy of an electron shell and \( \phi \) is the work function.

This Eq. (1) is used to obtain the kinetic energy of the Auger electron and it is presupposed that the sample surface is kept at the earth electric potential. However, in the case of the insulator sample, because the surface is not kept at the earth electric potential but in an electrically isolated state, the electrostatic energy of the actually measured electron is detected at the value with the surface potential \( V_S \) added to the kinetic energy of the Auger electron. Therefore, when you obtain the electrostatic energy \( U \) of the electron by taking the surface potential into consideration, it becomes as Eq. (2).

\[ U = K - V_S + \phi \cdots \cdots \cdots \cdots \cdots (2) \]

where, \( U \) is the electrostatic energy of the observed electron, \( K \) is the kinetic energy of the Auger electron, and \( V_S \) is the surface potential, which is the function of the position \( (x, y) \) of the sample surface and the time \( t \), and has a negative sign because the electron has the negative charge.

The energy of the electron measured using the Auger Electron Spectroscopy represents this electrostatic energy \( U \). In the case of the conductor sample, because the surface potential becomes always \( V_S = 0 \) regardless of the sample position, the equality \( U = K \) holds, the measured electrostatic energy corresponds directly to the kinetic energy of the Auger electron. On the other hand, in the case of the insulator sample, because the sample surface is in an electrically isolated state, even if the analysis position is fixed in place, because the magnitude of the surface potential changes depending on the amount of the incident electrons and the diffusion speed of the charged electrons, the electrostatic energy of the observed electron does not become stable.

This is a fatal problem in the Auger analysis. If the shift of the peak position changes by the fluctuation of the surface potential \( V_S \) due to the effect of charging in a sufficiently short time compared with the measurement time of the spectrum, it disturbs the accurate spectrum measurement. For example, the peaks become broader as in the superimposed spectrum shown in the right figure in Fig. 2 or a ghost peak appears. In order to perform Auger analysis with high accuracy, you need to search a condition to become \( V_S = \) (constant) regardless of the measurement time even if the surface potential \( V_S \) does not become zero.

A problem of charging when the electron beam enters the sample surface

This section describes the charging phenomenon when the electron beam enters into the sample. Fig. 3 shows an optical and a secondary electron image of a general printed circuit board on which Au electrodes are wired. In the secondary electron image, the glass epoxy resin portion exhibits a typical secondary electron image of charged material, revealing that the contrast is unstable and the secondary electron image

![Fig. 1 The emission process and the kinetic energy of an Auger electron.](image-url)
intensity fluctuates wildly. In order to analyze this phenomenon, the three situations are considered using the model as shown in Fig. 4.

When the electron beam enters the insulator sample surface, the incident electrons generate secondary electrons including Auger electrons, they escape from the sample as backscattered electrons or remain inside the sample as they are. Let the charge remained on the sample surface be \( Q \) as shown in Fig. 4, the following equation holds.

\[
Q_s = Q + (Q_e + Q_d) \quad \cdots (3)
\]

where, \( Q_1 \) is the charge entered into the sample as the incident electrons, \( Q_e \) is the charge escaped from the sample surface as the secondary and backscattered electrons, and \( Q_d \) is the charge leaked out of the sample due to the diffusion of the electrons. On this occasion, if the potential \( V_s \) on the insulator sample surface is assumed to form a capacitor between the insulator sample surface and the sample holder in the reverse side, it is expressed by the following equation.

\[
V_s = \frac{Q_s}{C_s} = \frac{1}{C_s} \{Q + (Q_e + Q_d)\} \quad \cdots (4)
\]

From Eq. (4), it is found that the surface potential \( V_s \) is proportional to \( Q \), and that the sign becomes either positive or negative depending on the charge difference between \( |Q_1| \) and \( |Q_e + Q_d| \). Next, the difference of each parameter according to the difference of \( Q_s \) is quantitatively shown in Fig. 5 based on the present model.

Fig. 5 shows three cases: (i) when the surface potential is positive, (ii) when the surface potential becomes negative, and (iii) when the charge becomes too large for the electron beam to enter into the sample surface because the surface potential becomes nearly equal to the accelerating voltage of the electron beam. The reason why the contrast of the secondary electron image becomes unstable or the electron intensity fluctuates wildly to result in obtaining an image that is entirely unmatched with the actual surface shape is mainly because the phenomenon of (iii) occurs. In the case of (iii), the Auger analysis is not possible because the electrons cannot enter into the sample surface.

In the second case (ii), however, you can observe a secondary electron image and measure an Auger spectrum at the beginning because the charge is small compared with the case (iii); Usually, this situation is not stable. As long as the incident charge meets the condition \( |Q_1| > |Q_e + Q_d| \), the surface charge increases and eventually results in the state (iii), making it impossible to perform the stable analysis.

As a conclusion, only if the surface potential satisfies \( V_s > 0 \) as in the case of (i), where the condition \( |Q_1| < |Q_e + Q_d| \) is satisfied, the electron beam can always enter the sample surface, making it possible to constantly perform the Auger analysis. If you observe an insulator sample itself or even a conductor sample when it is electrically isolated, you cannot perform a highly reliable measurement unless you create the state in which the surface potential becomes positive as in the case (i) using some method and then perform the Auger analysis. Specifically, to increase the escaped charge (\( Q_e \)) due to the secondary and backscattered electrons, you use the “Sample tilt method”, and to increase the leaked charge (\( Q_d \)) due to the diffusion, you only apply the “Charge suppression method using the neutralizer gun.” The details of these methods will be explained in the later sections.

A problem of charging when detecting the Auger electrons

The previous section has described a problem that the electron beam cannot enter the sample surface, but this section describes a problem that becomes unable to detect Auger electrons after generating them due to the effect of charging.

Auger spectra measured of one of Au electrodes shown in Fig. 3 are shown in Fig. 6. It should be noted here that although Au peaks near 2000 eV in the spectrum before irradiating Ar ions can be normally detected, the electrons with lower energy than 300 eV cannot be detected. Because the Au peaks at the high energy near 2000 eV are detected at the same energy as those of the standard spectrum, it is found that the surface potential of the Au electrode becomes the earth potential (0 V) as described before. On the other hand, the reason why the electrons with the lower energy cannot be detected is that the glass epoxy resin around the Au electrode is charged and that the secondary and Auger electrons generated from the Au electrode surface do not normally enter the detector due to the deflection caused by the electric field generated by the glass epoxy resin.

---

**Fig. 2** O KLL (SiO\(_2\)) spectrum and its superimposed spectrum when the surface potential \( V_s \) is changed (+5, 0, -5, -20 V).

**Fig. 3** An optical and a secondary electron image of a printed circuit board masked with an aluminum foil.

**Fig. 4** Charging model when the electron beam is entered on the surface of the insulator sample.
charge accumulated on the glass epoxy resin surrounding the electrode. Fig. 7 shows schematic diagrams illustrating the two possible cases: (i) when the glass epoxy resin around the electrode is negatively charged and (ii) when it is positively charged.

The diagram of the case (i) illustrates the circumstance in which the electron beam is irradiated on the glass epoxy resin surrounding the sample in order to confirm the analysis points on the sample and measure the secondary electron image, accumulating the electrons to negatively charge the glass epoxy resin. In this case, the negative electric field generated by the charging on the glass epoxy resin deflects the trajectory of the low energy electrons, causing a phenomenon that they do not enter the detector. For this reason, although the Au peaks at the high energy side as shown in Fig. 6 are not affected by the charging on the glass epoxy resin, it is obtained an abnormal spectrum in which the low energy electrons are not detected.

On the other hand, the case of (ii) is often encountered when Ar ions in stead of electrons accumulate on the glass epoxy resin surrounding the sample to positively charge the glass epoxy resin because you increase the Ar ion current to irradiate the sample using the neutralizer too much. In this case, similarly, the positive electric field generated by the charging on the glass epoxy resin deflects the trajectory of the low energy electrons, causing a phenomenon that they do not enter the detector. Also in this case, although the Au peaks at the high energy side as shown in Fig. 6 are not affected by the charging on the glass epoxy resin, it gives an abnormal spectrum in which the low energy electrons are not detected.

**Method for Suppressing Charging in the Auger Analysis**

**Sample tilt method**

Up to the previous section, it is shown that keeping the surface potential constant is necessary to measure the Auger electrons and that controlling the surrounding charging state is also necessary when detecting the Auger electrons. This section describes the sample tilt method that increases $Q_S$ as a method for creating the state of the surface potential $V_S > 0$.
As in the case (i) in Fig. 5.

If you tilt the sample in the Auger analysis, the emission yield of secondary electrons increases because the incident angle of the electron beam becomes shallower and the region to excite the secondary electrons comes closer to the sample surface. Fig. 8 shows the relation between the sample tilt angle \( \theta \) and the incident angle of the electron beam.

When the incident direction of the electron beam is tilted by \( \theta \) from the vertical direction of the sample, suppose that secondary electrons are generated along the length \( L \) as shown in Fig. 8. Supposing that the secondary electrons generated at each point along the length \( L \) are absorbed until they escape from the sample surface, the number of the secondary electrons generated from the sample surface is expressed as in Eq. (5). From this equation, it is found that the amount of the generated secondary electrons increases roughly in proportion to \( 1/\cos \theta \) as you increase the sample tilt angle \( \theta \). Therefore, if you simply tilt the sample, the secondary electrons are generated in larger numbers, enabling you to make the surface potential positive as a result.

\[
N = \int ne^{-x/k} dx = \int ne^{-x/L \cos \theta} dx = \frac{n}{\cos \theta} \int ne^{-x/L} dx = \frac{n}{\cos \theta} \cdot N \tag{5}
\]

\( N \) : The number of secondary electrons generated from the sample surface

\( n \) : The number of secondary electrons generated per unit length

\( k \) : A attenuation coefficient

\( x \) : Distance from the emission point of secondary electrons to the surface (\( x = L \cos \theta \))

When you tilt the sample, not only the secondary electrons are generated in larger numbers, but also you can reduce the charge. Figure 9 shows the remaining rate of the incident electrons inside the sample obtained from the Monte Carlo simulation.

It is found in Fig. 9 that the amount of electrons escaping from the sample as the backscattered electrons among the incident electrons increases and the amount of electrons remained inside the sample decreases as the sample tilt angle increases. In the case of the insulator sample, the large remaining rate of the incident electrons shows that the sample is strongly charged, and the larger you make the sample tilt angle, the smaller the remaining rate of the incident electrons and the smaller the charge on the sample surface.

As described above, if you tilt the sample, the generated secondary electrons increase and the amount of the incident electrons remaining inside the sample decreases; so if you tilt the sample more than a certain angle, the emission amount of the secondary electrons exceeds the remaining amount of the incident electrons, resulting the sample surface charged positively. This is the method for suppressing charging by the sample tilt method.

Figure 10 shows the secondary electron images of the kapton surface at three sample tilt angles, and Figure 11 shows the Auger spectra of the sample surfaces. It is found that although unstable contrast and intensity variation characteristic of charging appear up to the tilt angle 60°, at the tilt angle 75°, a relatively stable secondary electron image and the normal Auger spectrum can be obtained.

### Charging suppression method using the neutralizer gun

A charging suppression method using the neutralizer gun is a method for suppressing charging produced on the sample surface by irradiating the positively charged low energy (about 10 to 50 eV) Ar ions on the surface of the insulator sample. Fig. 12 shows the schematic diagram.

Owing to the electron beam irradiated on the insulator sample to confirm the analysis position, charging due to electrons on the insulator surface occurs to produce negative surface potential. If you irradiate low energy Ar ions on this charged surface, even if it is non-uniformly charged, the Ar ions are attracted in proportion to charge and the charging on the insulator surface is suppressed uniformly. Here, the point to notice is that the beam diameter of the Ar ion beam employed in this neutralization is 50 thousand times larger than that of the electron beam; and even if their beam currents are the same, the current densities are entirely different, so the Ar ion beam cannot suppress the charging at the position just on which the electron beam is irradiated. The purpose of the neutralization is solely to...
act Ar ions for the circumference around the analysis position to suppress the surrounding non-uniform charging (2).

In addition, the Ar ions have a role to absorb and diffuse the electrons, which are hard to diffuse and disappear inside the sample, on the sample surface by appropriately distributing on the charged sample surface. In other words, this low-speed Ar ion irradiation method corresponds to a method for increasing the amount of Qs to create the state of the surface potential Vs > 0, as in the case (i) in Fig. 5, and has a large role to alleviate the charging phenomenon as shown in Fig. 13.

Confirming the charging state using the Auger spectrum

Although the charging on the sample is suppressed using two methods: "Sample tilt method" and "Charging suppression method using the neutralizer gun," you can judge whether the charge suppression is sufficient or insufficient from the Auger spectrum. Fig. 14 shows the Auger spectrum of the ungrounded electrode surface, and Fig. 15 shows the Auger spectrum of the grounded electrode surface. Looking at Fig. 14, it is found that all Au peaks in the spectrum of the ungrounded electrode surface are shifted forward higher energy and do not appear at their original positions. This is because the gold electrode is negatively charged by the electron beam, causing a negative surface potential and all the secondary electrons generated there are measured at higher energy by the surface potential according to Eq. (2).

As described above, if you continue to enter the electron beam on the condition where the surface potential is negative, the surface potential gradually grows in the negative side and does not also remain stable so that you cannot measure a reproducible spectrum. In this way, if a negative surface potential is formed on the sample surface, you need to adjust the measurement condition by applying the sample tilt method, decreasing the accelerating voltage, and performing other methods so that the Au peaks of the measurement target surely become the shifted states (positive surface potentials) to the low energy side than the original energy values.

On the other hand, as shown in Fig. 15, for the Auger spectrum of the grounded electrode surface, all Au peaks are measured at normal positions irrespective of the condition where the Au electrode is grounded or not, revealing that the gold electrode surface is the earth potential. In addition, by turning on the neutralizer gun, the charging on the glass epoxy resin surrounding the Au electrode disappears and the normal Auger spectrum is obtained. When you measure an Au electrode like this occasion, you can judge whether the Au electrode is grounded or not from the information that whether all the Au peaks are detected at the original peak positions or not.

Fig. 12 Schematic diagram of a suppression method of charging using Ar ions.

Fig. 13 Variation of the secondary electron images before and after the neutralization process in the Au electrode.

(a) Before irradiation of Ar ions
(b) After irradiation of Ar ions

Fig. 14 Auger spectra of the ungrounded Au electrode surface.

(Probe condition: 10 kV, 10 nA; sample tilt angle: 30°)

Fig. 15 Auger spectra of the grounded Au electrode surface.

(Probe condition: 10 kV, 10 nA; sample tilt angle: 30°)

Concluding Remarks

In the Auger analysis, from the feature of conducting the element analysis at a few nm from the surface, you cannot use the charge prevention processing by the surface conductor coating that is generally employed in the SEM and EPMA. In addition, in the Auger analysis, because the incident probe is electrons and the detection signal is also electrons, if the sample is charged even a little, the spectrum deforms, making it difficult to analyze the sample. It is shown, however, that if you understand what happens on the sample surface and properly deal with the problem, you can perform the Auger analysis. For example, the problem that you cannot analyze an electrode on a printed circuit board is often caused by the fact that the Au electrode of the measurement target is not grounded even while you have placed too much trust in the charging suppression method using the neutralizer gun. We hope you find the methods presented in this article informative.

References

